

# 8-bit Microcontroller

CMOS

## F<sup>2</sup>MC-8FX MB95200H/210H Series

**MB95F204H/F204K/F203H/F203K/F202H/F202K**  
**MB95F214H/F214K/F213H/F213K/F212H/F212K**

### ■ DESCRIPTION

MB95200H/210H is a series of general-purpose, single-chip microcontrollers. In addition to a compact instruction set, the microcontrollers of this series contain a variety of peripheral resources.

Note: F<sup>2</sup>MC is the abbreviation of FUJITSU Flexible Microcontroller.

### ■ FEATURES

- F<sup>2</sup>MC-8FX CPU core
  - Instruction set optimized for controllers
    - Multiplication and division instructions
    - 16-bit arithmetic operations
    - Bit test branch instructions
    - Bit manipulation instructions, etc.
- Clock (main OSC clock and sub-OSC clock are only available in **MB95F204H/F204K/F203H/F203K/F202H/F202K**)
  - Selectable main clock source
    - Main OSC clock (up to 16.25 MHz, maximum machine clock frequency: 8.125 MHz)
    - External clock (up to 32.5 MHz, maximum machine clock frequency: 16.25 MHz)
    - Main internal CR clock (1/8/10 MHz ± 3%, maximum machine clock frequency: 10 MHz)
  - Selectable subclock source
    - Sub-OSC clock (32.768 kHz)
    - External clock (32.768 kHz)
    - Sub-internal CR clock (typ: 100 kHz, min: 50 kHz, max: 200 kHz)
- Timer
  - 8/16-bit composite timer
  - Timebase timer
  - Watch prescaler
- LIN-UART (**MB95F204H/F204K/F203H/F203K/F202H/F202K**)
  - Full duplex double buffer
    - Capable of clock-synchronized serial data transfer and clock-asynchronized serial data transfer

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# MB95200H/210H Series

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- External interrupt
  - Interrupt by edge detection (rising edge, falling edge, and both edges can be selected)
  - Can be used to wake up the device from different low-power consumption (standby) modes
- 8/10-bit A/D converter
  - 8-bit or 10-bit resolution can be selected.
- Low power consumption (standby) mode
  - Stop mode
  - Sleep mode
  - Watch mode
  - Timebase timer mode
- I/O port (max: 17) (**MB95F204K/F203K/F202K**)
  - General-purpose I/O ports (max):  
CMOS I/O: 15, N-ch open drain: 2
- I/O port (max: 16) (**MB95F204H/F203H/F202H**)
  - General-purpose I/O ports (max):  
CMOS I/O: 15, N-ch open drain: 1
- I/O port (max: 5) (**MB95F214K/F213K/F212K**)
  - General-purpose I/O ports (max):  
CMOS I/O: 3, N-ch open drain: 2
- I/O port (max: 4) (**MB95F214H/F213H/F212H**)
  - General-purpose I/O ports (max):  
CMOS I/O: 3, N-ch open drain: 1
- On-chip debug
  - 1-wire serial control
  - Serial writing supported (asynchronous mode)
- Hardware/software watchdog timer
  - Built-in hardware watchdog timer
- Low-voltage detection reset circuit
  - Built-in low-voltage detector
- Clock supervisor counter
  - Built-in clock supervisor counter function
- Programmable port input voltage level
  - CMOS input level / hysteresis input level
- Flash memory security function
  - Protects the contents of flash memory

# MB95200H/210H Series

## ■ PRODUCT LINE-UP

Part number	MB95 F204H	MB95 F203H	MB95 F202H	MB95 F204K	MB95 F203K	MB95 F202K	MB95 F214H	MB95 F213H	MB95 F212H	MB95 F214K	MB95 F213K	MB95 F212K
Parameter												
Type	Flash memory product											
Clock supervisor counter	It supervises the main clock oscillation.											
ROM capacity	16 KB	8 KB	4 KB	16 KB	8 KB	4 KB	16 KB	8 KB	4 KB	16 KB	8 KB	4 KB
RAM capacity	496 B	496 B	240 B	496 B	496 B	240 B	496 B	496 B	240 B	496 B	496 B	240 B
Low-voltage detection reset	No			Yes			No			Yes		
Reset input	Dedicated			Software select			Dedicated			Software select		
CPU functions	Number of basic instructions : 136 Instruction bit length : 8 bits Instruction length : 1 to 3 bytes Data bit length : 1, 8, and 16 bits Minimum instruction execution time : 61.5 ns (with machine clock = 16.25 MHz) Interrupt processing time : 0.6 μs (with machine clock = 16.25 MHz)											
General-purpose I/O	I/O ports (max): 16 CMOS: 15, N-ch: 1			I/O ports (max): 17 CMOS: 15, N-ch: 2			I/O ports (max): 4 CMOS: 3, N-ch: 1			I/O ports (max): 5 CMOS: 3, N-ch: 2		
Timebase timer	Interrupt cycle : 0.256 ms - 8.3 s (when external clock = 4 MHz)											
Hardware/software watchdog timer	Reset generation cycle Main oscillation clock at 10 MHz : 105 ms (min) The sub-internal CR clock can be used as the source clock of the hardware watchdog.											
Wild register	It can be used to replace three bytes of data.											
LIN-UART	A wide range of communication speed can be selected by a dedicated reload timer. It has a full duplex double buffer. Clock-synchronized serial data transfer and clock-asynchronized serial data transfer is enabled. The LIN function can be used as a LIN master or a LIN slave.						No LIN-UART					
8/10-bit A/D converter	6 ch. 8-bit or 10-bit resolution can be selected.						2 ch.					
8/16-bit composite timer	2 ch. The timer can be configured as an "8-bit timer x 2 channels" or a "16-bit timer x 1 channel". It has built-in timer function, PWC function, PWM function and input capture function. Count clock: it can be selected from internal clocks (seven types) and external clocks. It can output square wave.						1 ch.					
External interrupt	6 ch. Interrupt by edge detection (rising edge, falling edge, or both edges can be selected.) It can be used to wake up the device from standby modes.						2 ch.					
On-chip debug	1-wire serial control It supports serial writing. (asynchronous mode)											

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# MB95200H/210H Series

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Part number	MB95 F204H	MB95 F203H	MB95 F202H	MB95 F204K	MB95 F203K	MB95 F202K	MB95 F214H	MB95 F213H	MB95 F212H	MB95 F214K	MB95 F213K	MB95 F212K
Parameter												
Watch prescaler	Eight different time intervals can be selected.											
Flash memory	<p>It supports automatic programming, Embedded Algorithm, write/erase/erase-suspend/erase-resume commands.</p> <p>It has a flag indicating the completion of the operation of Embedded Algorithm.</p> <p>Number of write/erase cycles (min): 100000</p> <p>Data retention time: 20 years</p> <p>For write/erase, external Vpp(+10 V) input is required.</p> <p>Flash Security Feature for protecting the contents of the flash</p>											
Standby mode	Sleep mode, stop mode, watch mode, timebase timer mode											
Package	SDIP-24 SOP-20						DIP-8 SOP-8					

# MB95200H/210H Series

## ■ PACKAGES AND CORRESPONDING PRODUCTS

Part number Package	MB95 F204H	MB95 F203H	MB95 F202H	MB95 F204K	MB95 F203K	MB95 F202K	MB95 F214H	MB95 F213H	MB95 F212H	MB95 F214K	MB95 F213K	MB95 F212K
24-pin plastic SDIP	O	O	O	O	O	O	X	X	X	X	X	X
20-pin plastic SOP	O	O	O	O	O	O	X	X	X	X	X	X
8-pin plastic DIP	X	X	X	X	X	X	O	O	O	O	O	O
8-pin plastic SOP	X	X	X	X	X	X	O	O	O	O	O	O

O: Available

X: Unavailable

## ■ DIFFERENCES AMONG PRODUCTS AND NOTES ON PRODUCT SELECTION

- Current consumption

When using the on-chip debug function, take account of the current consumption of flash erase/program.

For details of current consumption, see “■ ELECTRICAL CHARACTERISTICS”.

- Package

For details of information on each package, see “■ PACKAGES AND CORRESPONDING PRODUCTS” and “■ PACKAGE DIMENSIONS”.

- Operating voltage

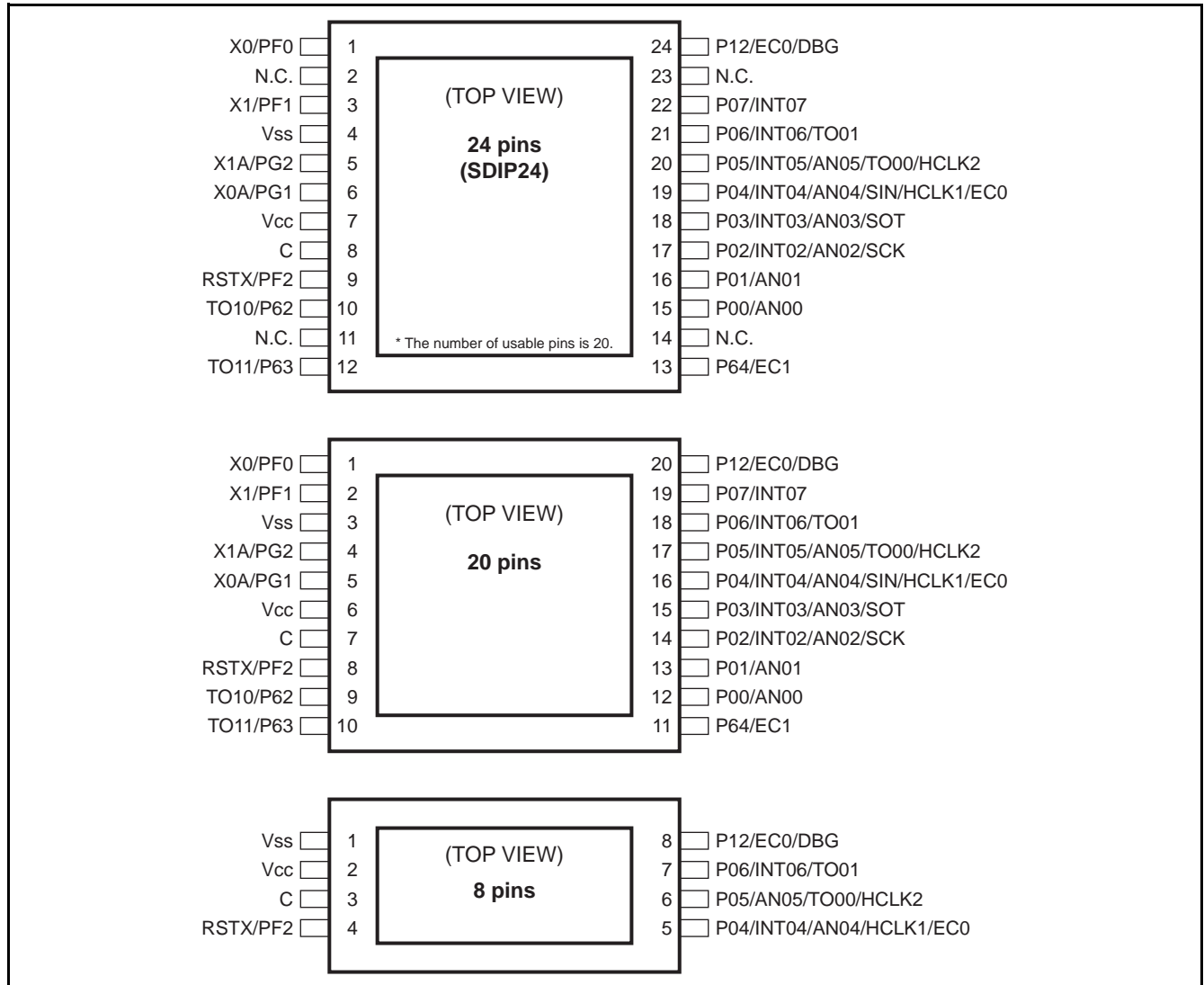
The operating voltage varies, depending on whether the on-chip debug function is used or not.

For details of the operating voltage, see “■ ELECTRICAL CHARACTERISTICS”.

- On-chip debug function

The on-chip debug function requires that  $V_{CC}$ ,  $V_{SS}$  and 1 serial-wire be connected to an evaluation tool. In addition, if the flash memory data has to be updated, the RSTX/PF2 pin must also be connected to the same evaluation tool.

## PIN ASSIGNMENT



# MB95200H/210H Series

## ■ PIN DESCRIPTION (MB95200H Series)

Pin no.	Pin name	I/O circuit type*	Function
1	PF0/X0	B	General-purpose I/O port This pin is also used as the main clock input oscillation pin.
2	PF1/X1	B	General-purpose I/O port This pin is also used as the main clock input/output oscillation pin.
3	V <sub>SS</sub>	—	Power supply pin (GND)
4	PG2/X1A	C	General-purpose I/O port This pin is also used as the subclock input/output oscillation pin.
5	PG1/X0A	C	General-purpose I/O port This pin is also used as the subclock input oscillation pin.
6	V <sub>CC</sub>	—	Power supply pin
7	C	—	Capacitor connection pin
8	PF2/RSTX	A	General-purpose I/O port This pin is also used as a reset pin. This pin is a dedicated reset pin in MB95F204H/F203H/F202H.
9	P62/TO10	D	General-purpose I/O port High-current port This pin is also used as the 8/16-bit composite timer ch. 1 output.
10	P63/TO11	D	General-purpose I/O port High-current port This pin is also used as the 8/16-bit composite timer ch. 1 output.
11	P64/EC1	D	General-purpose I/O port This pin is also used as the 8/16-bit composite timer ch. 1 clock input.
12	P00/AN00	E	General-purpose I/O port This pin is also used as the A/D converter analog input.
13	P01/AN01	E	General-purpose I/O port This pin is also used as the A/D converter analog input.
14	P02/INT02/AN02/ SCK	E	General-purpose I/O port This pin is also used as the external interrupt input. This pin is also used as the A/D converter analog input. This pin is also used as the LIN-UART clock I/O.
15	P03/INT03/AN03/ SOT	E	General-purpose I/O port This pin is also used as the external interrupt input. This pin is also used as the A/D converter analog input. This pin is also used as the LIN-UART data output.
16	P04/INT04/AN04/ SIN/HCLK1/EC0	F	General-purpose I/O port This pin is also used as the external interrupt input. This pin is also used as the A/D converter analog input. This pin is also used as the LIN-UART data input. This pin is also used as the external clock input. This pin is also used as the 8/16-bit composite timer ch. 0 clock input.

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Pin no.	Pin name	I/O circuit type*	Function
17	P05/INT05/AN05/ TO00/HCLK2	E	General-purpose I/O port High-current port This pin is also used as the external interrupt input. This pin is also used as the A/D converter analog input. This pin is also used as the 8/16-bit composite timer ch. 0 output. This pin is also used as the external clock input.
18	P06/INT06/TO01	G	General-purpose I/O port High-current port This pin is also used as the external interrupt input. This pin is also used as the 8/16-bit composite timer ch. 0 output.
19	P07/INT07	G	General-purpose I/O port This pin is also used as the external interrupt input.
20	P12/EC0/DBG	H	General-purpose I/O port This pin is also used as the DBG input pin. This pin is also used as the 8/16-bit composite timer ch. 0 clock input.

\*: For the I/O circuit types, see "■ I/O CIRCUIT TYPE".

# MB95200H/210H Series

## ■ PIN DESCRIPTION (MB95210H Series)

Pin no.	Pin name	I/O circuit type*	Function
1	V <sub>SS</sub>	—	Power supply pin (GND)
2	V <sub>CC</sub>	—	Power supply pin
3	C	—	Capacitor connection pin
4	RSTX/PF2	A	General-purpose I/O port This pin is also used as a reset pin. This pin is a dedicated reset pin in MB95F214H/F213H/F212H.
5	P04/INT04/AN04/ HCLK1/EC0	E	General-purpose I/O port This pin is also used as the external interrupt input. This pin is also used as the A/D converter analog input. This pin is also used as the external clock input. This pin is also used as the 8/16-bit composite timer ch. 0 clock input.
6	P05/AN05/TO00/ HCLK2	E	General-purpose I/O port High-current port This pin is also used as the A/D converter analog input. This pin is also used as the 8/16-bit composite timer ch. 0 output. This pin is also used as the external clock input.
7	P06/INT06/TO01	G	General-purpose I/O port High-current port This pin is also used as the external interrupt input. This pin is also used as the 8/16-bit composite timer ch. 0 output.
8	P12/EC0/DBG	H	General-purpose I/O port This pin is also used as the DBG input pin. This pin is also used as the 8/16-bit composite timer ch. 0 clock input.

\*: For the I/O circuit types, see "■ I/O CIRCUIT TYPE".

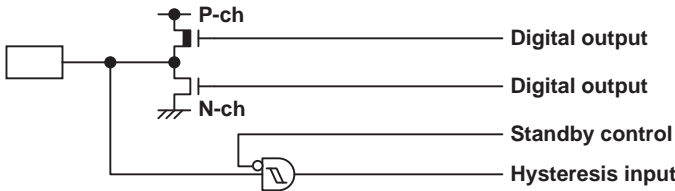
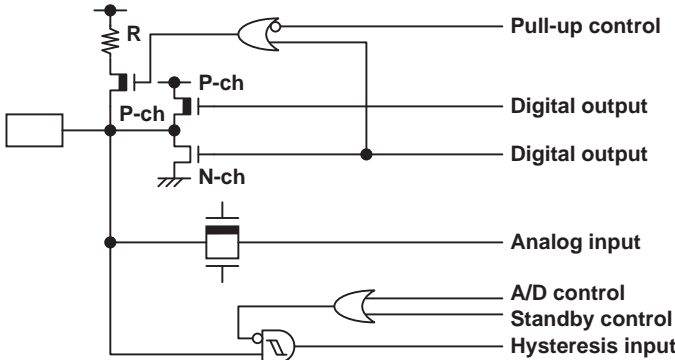
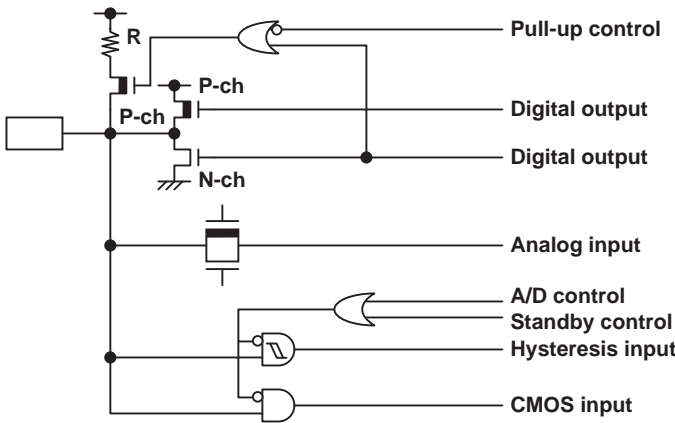
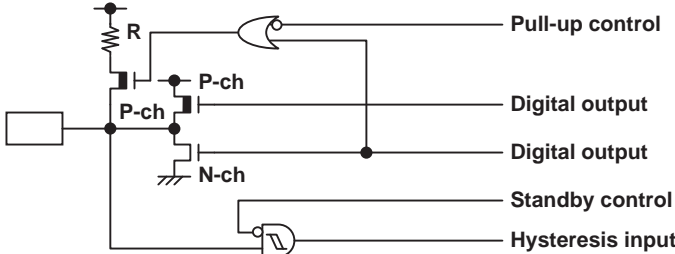
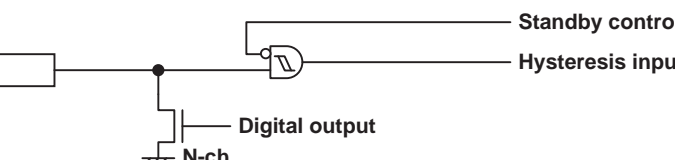
## ■ I/O CIRCUIT TYPE

Type	Circuit	Remarks
A		<ul style="list-style-type: none"> <li>• N-ch open drain output</li> <li>• Hysteresis input</li> <li>• Reset output</li> </ul>
B		<ul style="list-style-type: none"> <li>• Oscillation circuit</li> <li>• High-speed side Feedback resistance: approx. 1 MΩ</li> <li>• CMOS output</li> <li>• Hysteresis input</li> </ul>
C		<ul style="list-style-type: none"> <li>• Oscillation circuit</li> <li>• Low-speed side Feedback resistance: approx. 10 MΩ</li> <li>• CMOS output</li> <li>• Hysteresis input</li> <li>• Pull-up control available</li> </ul>

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# MB95200H/210H Series

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Type	Circuit	Remarks
D	 <p>             Digital output              Digital output              Standby control              Hysteresis input           </p>	<ul style="list-style-type: none"> <li>• CMOS output</li> <li>• Hysteresis input</li> </ul>
E	 <p>             Pull-up control              Digital output              Digital output              Analog input              A/D control              Standby control              Hysteresis input           </p>	<ul style="list-style-type: none"> <li>• CMOS output</li> <li>• Hysteresis input</li> <li>• Pull-up control available</li> </ul>
F	 <p>             Pull-up control              Digital output              Digital output              Analog input              A/D control              Standby control              Hysteresis input              CMOS input           </p>	<ul style="list-style-type: none"> <li>• CMOS output</li> <li>• Hysteresis input</li> <li>• CMOS input</li> <li>• Pull-up control available</li> </ul>
G	 <p>             Pull-up control              Digital output              Digital output              Standby control              Hysteresis input           </p>	<ul style="list-style-type: none"> <li>• Hysteresis input</li> <li>• CMOS output</li> <li>• Pull-up control available</li> </ul>
H	 <p>             Standby control              Hysteresis input              Digital output              N-ch           </p>	<ul style="list-style-type: none"> <li>• N-ch open drain output</li> <li>• Hysteresis input</li> </ul>

## ■ NOTES ON DEVICE HANDLING

- Preventing latch-ups

When using the device, ensure that the voltage applied does not exceed the maximum voltage rating.

In a CMOS IC, if a voltage higher than  $V_{CC}$  or a voltage lower than  $V_{SS}$  is applied to an input/output pin that is neither a medium-withstand voltage pin nor a high-withstand voltage pin, or if a voltage out of the rating range of power supply voltage mentioned in “1. Absolute Maximum Ratings” of ■ ELECTRICAL CHARACTERISTICS” is applied to the  $V_{CC}$  pin or the  $V_{SS}$  pin, a latch-up may occur.

When a latch-up occurs, power supply current increases significantly, which may cause a component to be thermally destroyed.

- Stabilizing supply voltage

Supply voltage must be stabilized.

A malfunction may occur when power supply voltage fluctuates rapidly even though the fluctuation is within the guaranteed operating range of the  $V_{CC}$  power supply voltage.

As a rule of voltage stabilization, suppress voltage fluctuation so that the fluctuation in  $V_{CC}$  ripple (p-p value) at the commercial frequency (50 Hz/60 Hz) does not exceed 10% of the standard  $V_{CC}$  value, and the transient fluctuation rate does not exceed 0.1 V/ms at a momentary fluctuation such as switching the power supply.

- Notes on using the external clock

When an external clock is used, oscillation stabilization wait time is required for power-on reset, wake-up from subclock mode or stop mode.

## ■ PIN CONNECTION

- Treatment of unused pins

If an unused input pin is left unconnected, a component may be permanently damaged due to malfunctions or latch-ups. Always pull up or pull down an unused input pin through a resistor of at least 2 k $\Omega$ . Set an unused input/output pin to the output state and leave it unconnected, or set it to the input state and treat it the same as an unused input pin. If there is an unused output pin, leave it unconnected.

- Power supply pins

To reduce unnecessary electro-magnetic emission, prevent malfunctions of strobe signals due to an increase in the ground level, and conform to the total output current standard, always connect the  $V_{CC}$  pin and the  $V_{SS}$  pin to the power supply and ground outside the device. In addition, connect the current supply source to the  $V_{CC}$  pin and the  $V_{SS}$  pin with low impedance.

It is also advisable to connect a ceramic bypass capacitor of approximately 0.1  $\mu$ F between the  $V_{CC}$  pin and the  $V_{SS}$  pin at a location close to this device.

- DBG pin

Connect the DBG pin directly to an external pull-up resistor.

To prevent the device from unintentionally entering the debug mode due to noise, minimize the distance between the DBG pin and the  $V_{CC}$  or  $V_{SS}$  pin when designing the layout of the printed circuit board.

The DBG pin should not stay at “L” level after power-on until the reset output is released.

- RSTX pin

Connect the RSTX pin directly to an external pull-up resistor.

To prevent the device from unintentionally entering the reset mode due to noise, minimize the distance between the RSTX pin and the  $V_{CC}$  or  $V_{SS}$  pin when designing the layout of the printed circuit board.

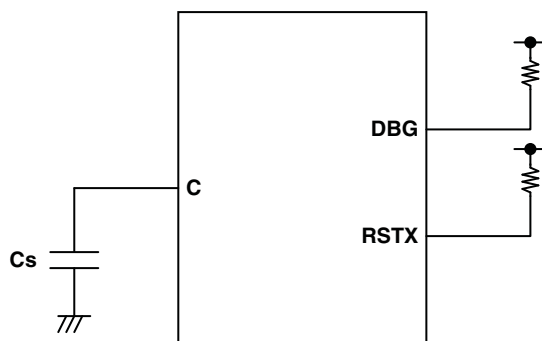
The RSTX/PF2 pin functions as the reset input/output pin after power-on. In addition, the reset output can be enabled by the RSTOE bit of the SYSC register, and the reset input function or the general purpose I/O function can be selected by the RSTEN bit of the SYSC register.

# MB95200H/210H Series

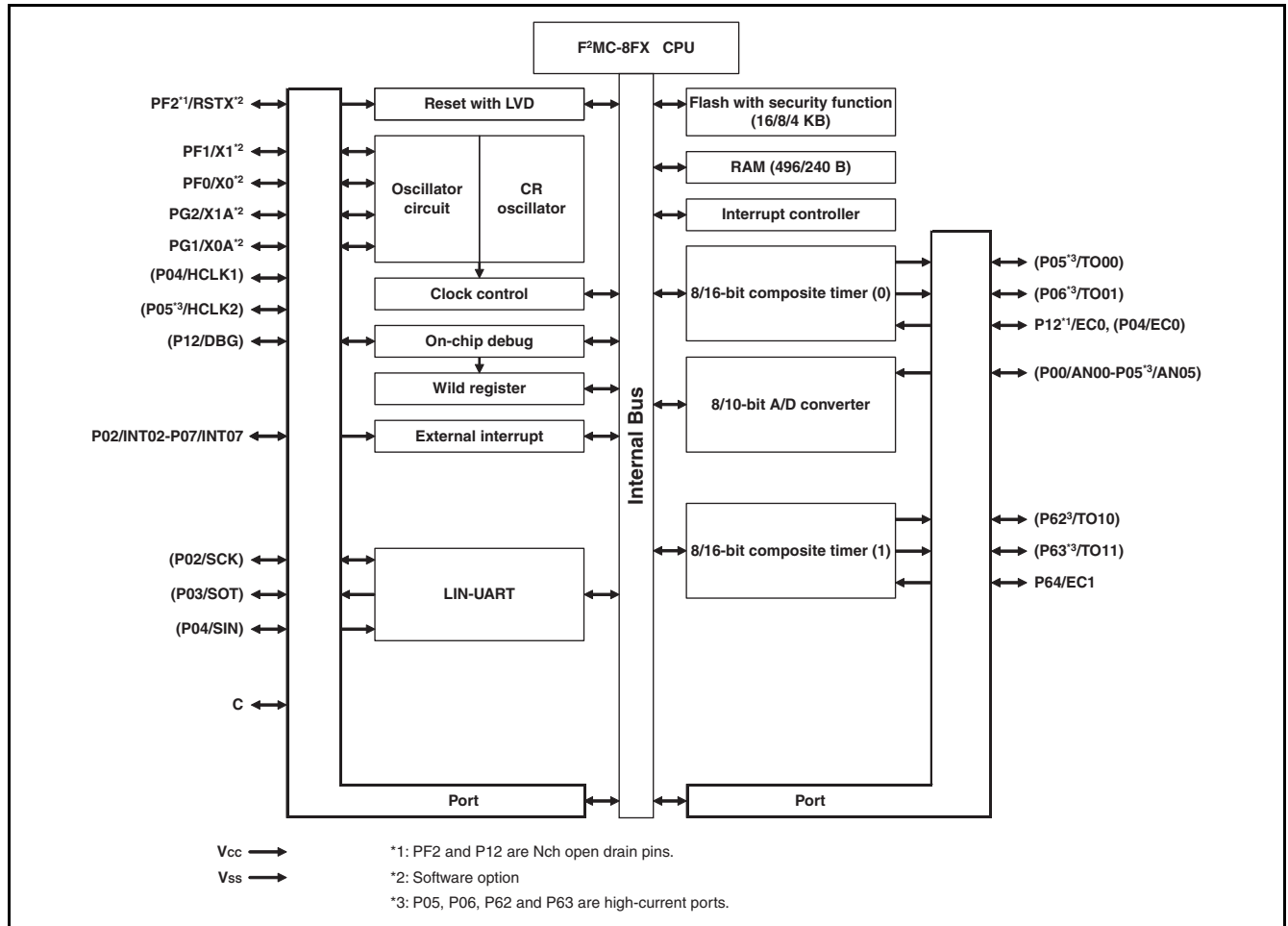
- C pin

Use a ceramic capacitor or a capacitor with equivalent frequency characteristics. The bypass capacitor for the  $V_{CC}$  pin must have a capacitance larger than  $C_s$ . For the connection to a smoothing capacitor  $C_s$ , see the diagram below. To prevent the device from unintentionally entering an unknown mode due to noise, minimize the distance between the C pin and  $C_s$  and the distance between  $C_s$  and the  $V_{SS}$  pin when designing the layout of a printed circuit board.

- DBG/RSTX/C pin connection diagram

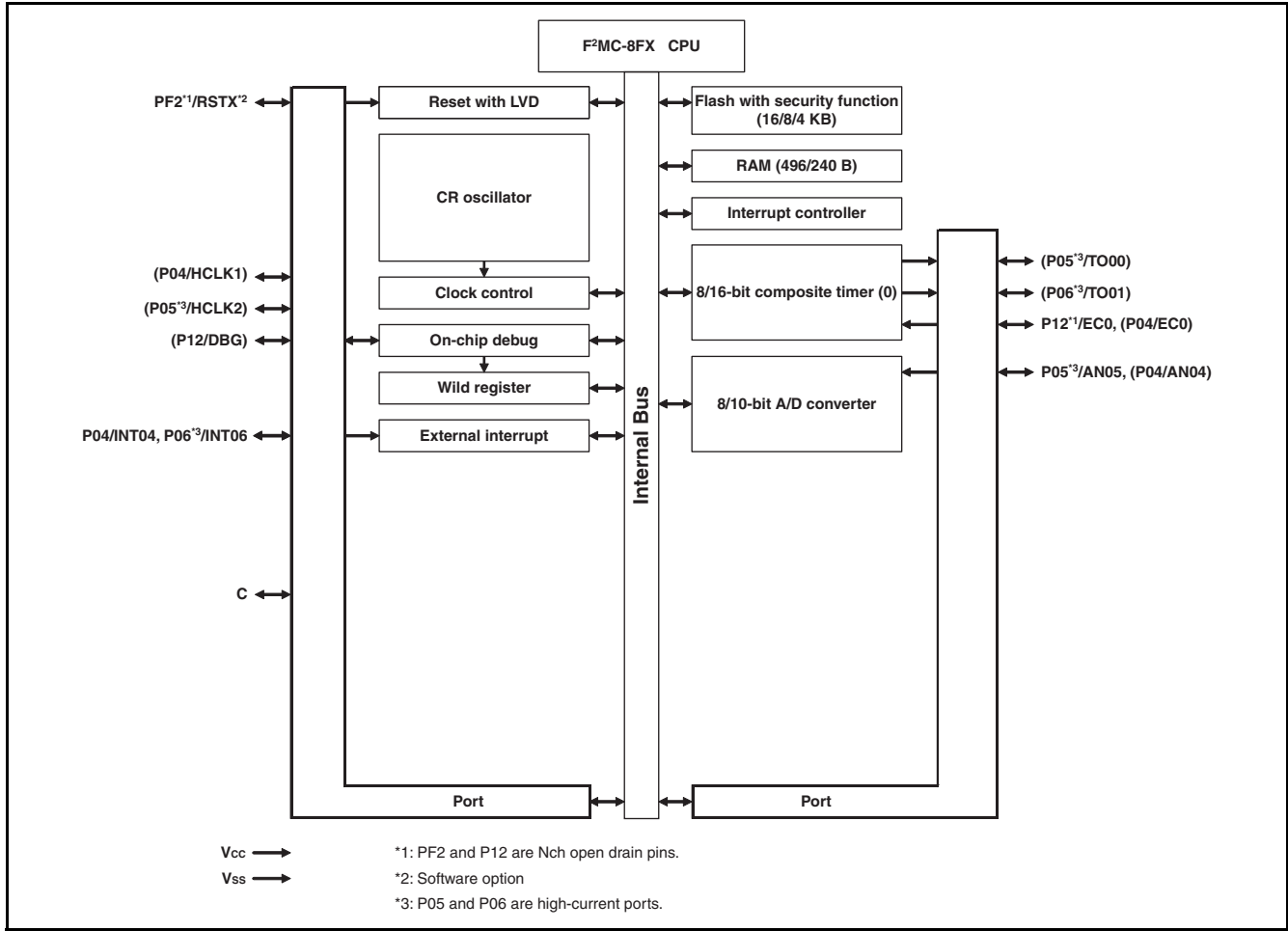


## ■ BLOCK DIAGRAM (MB95200H Series)



# MB95200H/210H Series

## ■ BLOCK DIAGRAM (MB95210H Series)



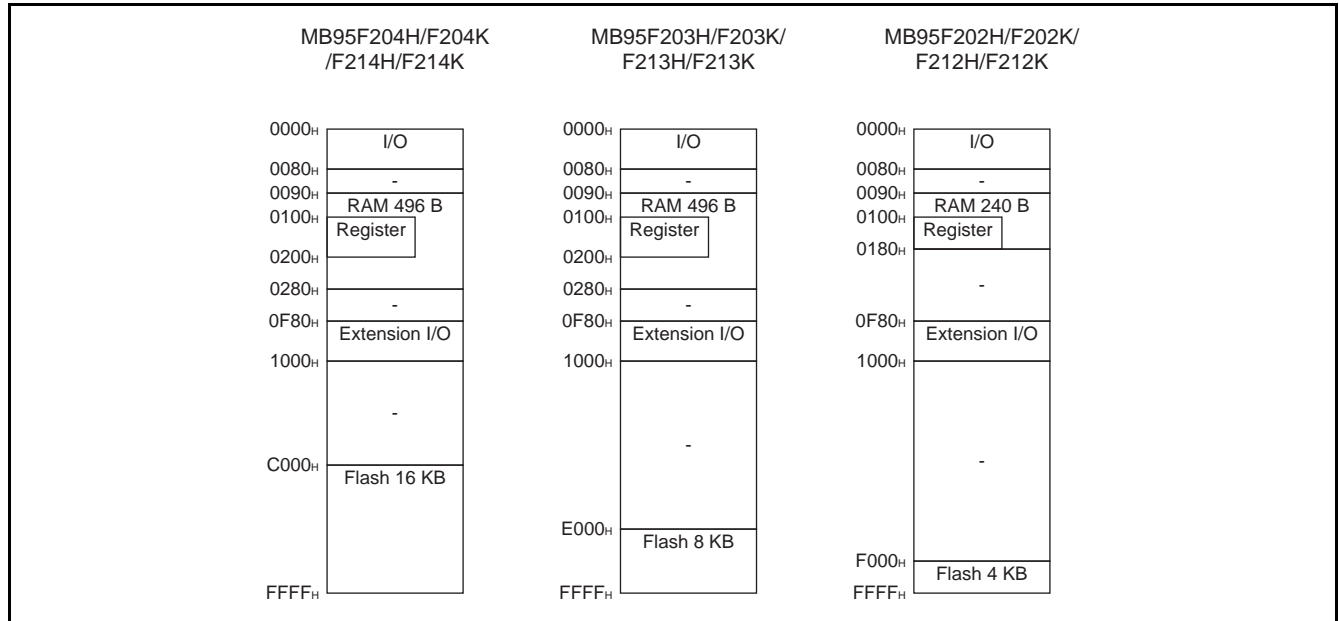


## ■ CPU CORE

### • Memory Space

The memory space of the MB95200H/210H Series is 64 KB in size, and consists of an I/O area, a data area, and a program area. The memory space includes areas intended for specific purposes such as general-purpose registers and a vector table. The memory maps of the MB95200H/210H Series are shown below.

### • Memory Maps



# MB95200H/210H Series

## ■ I/O MAP (MB95200H Series)

Address	Register abbreviation	Register name	R/W	Initial value
0000 <sub>H</sub>	PDR0	Port 0 data register	R/W	00000000 <sub>B</sub>
0001 <sub>H</sub>	DDR0	Port 0 direction register	R/W	00000000 <sub>B</sub>
0002 <sub>H</sub>	PDR1	Port 1 data register	R/W	00000000 <sub>B</sub>
0003 <sub>H</sub>	DDR1	Port 1 direction register	R/W	00000000 <sub>B</sub>
0004 <sub>H</sub>	—	(Disabled)	—	—
0005 <sub>H</sub>	WATR	Oscillation stabilization wait time setting register	R/W	11111111 <sub>B</sub>
0006 <sub>H</sub>	—	(Disabled)	—	—
0007 <sub>H</sub>	SYCC	System clock control register	R/W	XXXXXX11 <sub>B</sub>
0008 <sub>H</sub>	STBC	Standby control register	R/W	00000XXX <sub>B</sub>
0009 <sub>H</sub>	RSRR	Reset source register	R	XXXXXXXX <sub>B</sub>
000A <sub>H</sub>	TBTC	Timebase timer control register	R/W	00000000 <sub>B</sub>
000B <sub>H</sub>	WPCR	Watch prescaler control register	R/W	00000000 <sub>B</sub>
000C <sub>H</sub>	WDTC	Watchdog timer control register	R/W	00000000 <sub>B</sub>
000D <sub>H</sub>	SYCC2	System clock control register 2	R/W	XX100011 <sub>B</sub>
000E <sub>H</sub> to 0015 <sub>H</sub>	—	(Disabled)	—	—
0016 <sub>H</sub>	PDR6	Port 6 data register	R/W	00000000 <sub>B</sub>
0017 <sub>H</sub>	DDR6	Port 6 direction register	R/W	00000000 <sub>B</sub>
0018 <sub>H</sub> to 0027 <sub>H</sub>	—	(Disabled)	—	—
0028 <sub>H</sub>	PDRF	Port F data register	R/W	00000000 <sub>B</sub>
0029 <sub>H</sub>	DDRF	Port F direction register	R/W	00000000 <sub>B</sub>
002A <sub>H</sub>	PDRG	Port G data register	R/W	00000000 <sub>B</sub>
002B <sub>H</sub>	DDRG	Port G direction register	R/W	00000000 <sub>B</sub>
002C <sub>H</sub>	PUL0	Port 0 pull-up register	R/W	00000000 <sub>B</sub>
002D <sub>H</sub> to 0034 <sub>H</sub>	—	(Disabled)	—	—
0035 <sub>H</sub>	PULG	Port G pull-up register	R/W	00000000 <sub>B</sub>
0036 <sub>H</sub>	T01CR1	8/16-bit composite timer 01 status control register 1 ch. 0	R/W	00000000 <sub>B</sub>
0037 <sub>H</sub>	T00CR1	8/16-bit composite timer 00 status control register 1 ch. 0	R/W	00000000 <sub>B</sub>
0038 <sub>H</sub>	T11CR1	8/16-bit composite timer 11 status control register 1 ch. 1	R/W	00000000 <sub>B</sub>
0039 <sub>H</sub>	T10CR1	8/16-bit composite timer 10 status control register 1 ch. 1	R/W	00000000 <sub>B</sub>
003A <sub>H</sub> to 0048 <sub>H</sub>	—	(Disabled)	—	—
0049 <sub>H</sub>	EIC10	External interrupt circuit control register ch. 2/ch. 3	R/W	00000000 <sub>B</sub>

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# MB95200H/210H Series

Address	Register abbreviation	Register name	R/W	Initial value
004A <sub>H</sub>	EIC20	External interrupt circuit control register ch. 4/ch. 5	R/W	00000000 <sub>B</sub>
004B <sub>H</sub>	EIC30	External interrupt circuit control register ch. 6/ch. 7	R/W	00000000 <sub>B</sub>
004C <sub>H</sub> to 004F <sub>H</sub>	—	(Disabled)	—	—
0050 <sub>H</sub>	SCR	LIN-UART serial control register	R/W	00000000 <sub>B</sub>
0051 <sub>H</sub>	SMR	LIN-UART serial mode register	R/W	00000000 <sub>B</sub>
0052 <sub>H</sub>	SSR	LIN-UART serial status register	R/W	00001000 <sub>B</sub>
0053 <sub>H</sub>	RDR/TDR	LIN-UART receive/transmit data register	R/W	00000000 <sub>B</sub>
0054 <sub>H</sub>	ESCR	LIN-UART extended status control register	R/W	00000100 <sub>B</sub>
0055 <sub>H</sub>	ECCR	LIN-UART extended communication control register	R/W	000000XX <sub>B</sub>
0056 <sub>H</sub> to 006B <sub>H</sub>	—	(Disabled)	—	—
006C <sub>H</sub>	ADC1	8/10-bit A/D converter control register 1	R/W	00000000 <sub>B</sub>
006D <sub>H</sub>	ADC2	8/10-bit A/D converter control register 2	R/W	00000000 <sub>B</sub>
006E <sub>H</sub>	ADDH	8/10-bit A/D converter data register (Upper)	R/W	00000000 <sub>B</sub>
006F <sub>H</sub>	ADDL	8/10-bit A/D converter data register (Lower)	R/W	00000000 <sub>B</sub>
0070 <sub>H</sub> to 0071 <sub>H</sub>	—	(Disabled)	—	—
0072 <sub>H</sub>	FSR	Flash memory status register	R/W	000X0000 <sub>B</sub>
0073 <sub>H</sub> to 0075 <sub>H</sub>	—	(Disabled)	—	—
0076 <sub>H</sub>	WREN	Wild register address compare enable register	R/W	00000000 <sub>B</sub>
0077 <sub>H</sub>	WROR	Wild register data test setting register	R/W	00000000 <sub>B</sub>
0078 <sub>H</sub>	—	Mirror of register bank pointer (RP) and direct bank pointer (DP)	—	—
0079 <sub>H</sub>	ILR0	Interrupt level setting register 0	R/W	11111111 <sub>B</sub>
007A <sub>H</sub>	ILR1	Interrupt level setting register 1	R/W	11111111 <sub>B</sub>
007B <sub>H</sub>	ILR2	Interrupt level setting register 2	R/W	11111111 <sub>B</sub>
007C <sub>H</sub>	ILR3	Interrupt level setting register 3	R/W	11111111 <sub>B</sub>
007D <sub>H</sub>	ILR4	Interrupt level setting register 4	R/W	11111111 <sub>B</sub>
007E <sub>H</sub>	ILR5	Interrupt level setting register 5	R/W	11111111 <sub>B</sub>
007F <sub>H</sub>	—	(Disabled)	—	—
0F80 <sub>H</sub>	WRARH0	Wild register address setting register (Upper) ch. 0	R/W	00000000 <sub>B</sub>

(Continued)

# MB95200H/210H Series

Address	Register abbreviation	Register name	R/W	Initial value
0F81 <sub>H</sub>	WRARL0	Wild register address setting register (Lower) ch. 0	R/W	00000000 <sub>B</sub>
0F82 <sub>H</sub>	WRDR0	Wild register data setting register ch. 0	R/W	00000000 <sub>B</sub>
0F83 <sub>H</sub>	WRARH1	Wild register address setting register (Upper) ch. 1	R/W	00000000 <sub>B</sub>
0F84 <sub>H</sub>	WRARL1	Wild register address setting register (Lower) ch. 1	R/W	00000000 <sub>B</sub>
0F85 <sub>H</sub>	WRDR1	Wild register data setting register ch. 1	R/W	00000000 <sub>B</sub>
0F86 <sub>H</sub>	WRARH2	Wild register address setting register (Upper) ch. 2	R/W	00000000 <sub>B</sub>
0F87 <sub>H</sub>	WRARL2	Wild register address setting register (Lower) ch. 2	R/W	00000000 <sub>B</sub>
0F88 <sub>H</sub>	WRDR2	Wild register data setting register ch. 2	R/W	00000000 <sub>B</sub>
0F89 <sub>H</sub> to 0F91 <sub>H</sub>	—	(Disabled)	—	—
0F92 <sub>H</sub>	T01CR0	8/16-bit composite timer 01 status control register 0 ch. 0	R/W	00000000 <sub>B</sub>
0F93 <sub>H</sub>	T00CR0	8/16-bit composite timer 00 status control register 0 ch. 0	R/W	00000000 <sub>B</sub>
0F94 <sub>H</sub>	T01DR	8/16-bit composite timer 01 data register ch. 0	R/W	00000000 <sub>B</sub>
0F95 <sub>H</sub>	T00DR	8/16-bit composite timer 00 data register ch. 0	R/W	00000000 <sub>B</sub>
0F96 <sub>H</sub>	TMCR0	8/16-bit composite timer 00/01 timer mode control register ch. 0	R/W	00000000 <sub>B</sub>
0F97 <sub>H</sub>	T11CR0	8/16-bit composite timer 11 status control register 0 ch. 1	R/W	00000000 <sub>B</sub>
0F98 <sub>H</sub>	T10CR0	8/16-bit composite timer 10 status control register 0 ch. 1	R/W	00000000 <sub>B</sub>
0F99 <sub>H</sub>	T11DR	8/16-bit composite timer 11 data register ch. 1	R/W	00000000 <sub>B</sub>
0F9A <sub>H</sub>	T10DR	8/16-bit composite timer 10 data register ch. 1	R/W	00000000 <sub>B</sub>
0F9B <sub>H</sub>	TMCR1	8/16-bit composite timer 10/11 timer mode control register ch. 1	R/W	00000000 <sub>B</sub>
0F9C <sub>H</sub> to 0FBB <sub>H</sub>	—	(Disabled)	—	—
0FBC <sub>H</sub>	BGR1	LIN-UART baud rate generator register 1	R/W	00000000 <sub>B</sub>
0FBD <sub>H</sub>	BGR0	LIN-UART baud rate generator register 0	R/W	00000000 <sub>B</sub>
0FBE <sub>H</sub> to 0FC2 <sub>H</sub>	—	(Disabled)	—	—
0FC3 <sub>H</sub>	AIDRL	A/D input disable register (Lower)	R/W	00000000 <sub>B</sub>
0FC4 <sub>H</sub> to 0FE3 <sub>H</sub>	—	(Disabled)	—	—
0FE4 <sub>H</sub>	CRTH	Main CR clock trimming register (Upper)	R/W	1XXXXXXX <sub>B</sub>
0FE5 <sub>H</sub>	CRTL	Main CR clock trimming register (Lower)	R/W	000XXXXX <sub>B</sub>

(Continued)

(Continued)

Address	Register abbreviation	Register name	R/W	Initial value
0FE6 <sub>H</sub> to 0FE7 <sub>H</sub>	—	(Disabled)	—	—
0FE8 <sub>H</sub>	SYSC	System configuration register	R/W	11000011 <sub>B</sub>
0FE9 <sub>H</sub>	CMCR	Clock monitoring control register	R/W	XX000000 <sub>B</sub>
0FEA <sub>H</sub>	CMDR	Clock monitoring data register	R/W	00000000 <sub>B</sub>
0FEB <sub>H</sub>	WDTH	Watchdog timer selection ID register (Upper)	R/W	XXXXXXXX <sub>B</sub>
0FEC <sub>H</sub>	WDTL	Watchdog timer selection ID register (Lower)	R/W	XXXXXXXX <sub>B</sub>
0FED <sub>H</sub>	—	(Disabled)	—	—
0FEE <sub>H</sub>	ILSR	Input level select register	R/W	00000000 <sub>B</sub>
0FEF <sub>H</sub> to 0FFF <sub>H</sub>	—	(Disabled)	—	—

• R/W access symbols

R/W : Readable / Writable

R : Read only

W : Write only

• Initial value symbols

0 : The initial value of this bit is “0”.

1 : The initial value of this bit is “1”.

X : The initial value of this bit is undefined.

Note: Do not write to an address that is “(Disabled)”. If a “(Disabled)” address is read, an undefined value is returned.

# MB95200H/210H Series

## ■ I/O MAP (MB95210H Series)

Address	Register abbreviation	Register name	R/W	Initial value
0000 <sub>H</sub>	PDR0	Port 0 data register	R/W	00000000 <sub>B</sub>
0001 <sub>H</sub>	DDR0	Port 0 direction register	R/W	00000000 <sub>B</sub>
0002 <sub>H</sub>	PDR1	Port 1 data register	R/W	00000000 <sub>B</sub>
0003 <sub>H</sub>	DDR1	Port 1 direction register	R/W	00000000 <sub>B</sub>
0004 <sub>H</sub>	—	(Disabled)	—	—
0005 <sub>H</sub>	WATR	Oscillation stabilization wait time setting register	R/W	11111111 <sub>B</sub>
0006 <sub>H</sub>	—	(Disabled)	—	—
0007 <sub>H</sub>	SYCC	System clock control register	R/W	XXXXXX11 <sub>B</sub>
0008 <sub>H</sub>	STBC	Standby control register	R/W	00000XXX <sub>B</sub>
0009 <sub>H</sub>	RSRR	Reset source register	R	XXXXXXXX <sub>B</sub>
000A <sub>H</sub>	TBTC	Timebase timer control register	R/W	00000000 <sub>B</sub>
000B <sub>H</sub>	WPCR	Watch prescaler control register	R/W	00000000 <sub>B</sub>
000C <sub>H</sub>	WDTC	Watchdog timer control register	R/W	00000000 <sub>B</sub>
000D <sub>H</sub>	SYCC2	System clock control register 2	R/W	XX100011 <sub>B</sub>
000E <sub>H</sub> to 0015 <sub>H</sub>	—	(Disabled)	—	—
0016 <sub>H</sub>	—	(Disabled)	—	—
0017 <sub>H</sub>	—	(Disabled)	—	—
0018 <sub>H</sub> to 0027 <sub>H</sub>	—	(Disabled)	—	—
0028 <sub>H</sub>	PDRF	Port F data register	R/W	00000000 <sub>B</sub>
0029 <sub>H</sub>	DDRF	Port F direction register	R/W	00000000 <sub>B</sub>
002A <sub>H</sub>	—	(Disabled)	—	—
002B <sub>H</sub>	—	(Disabled)	—	—
002C <sub>H</sub>	PUL0	Port 0 pull-up register	R/W	00000000 <sub>B</sub>
002D <sub>H</sub> to 0034 <sub>H</sub>	—	(Disabled)	—	—
0035 <sub>H</sub>	—	(Disabled)	—	—
0036 <sub>H</sub>	T01CR1	8/16-bit composite timer 01 status control register 1 ch. 0	R/W	00000000 <sub>B</sub>
0037 <sub>H</sub>	T00CR1	8/16-bit composite timer 00 status control register 1 ch. 0	R/W	00000000 <sub>B</sub>
0038 <sub>H</sub>	—	(Disabled)	—	—
0039 <sub>H</sub>	—	(Disabled)	—	—
003A <sub>H</sub> to 0048 <sub>H</sub>	—	(Disabled)	—	—
0049 <sub>H</sub>	—	(Disabled)	—	—

(Continued)

# MB95200H/210H Series

Address	Register abbreviation	Register name	R/W	Initial value
004A <sub>H</sub>	EIC20	External interrupt circuit control register ch. 4	R/W	00000000 <sub>B</sub>
004B <sub>H</sub>	EIC30	External interrupt circuit control register ch. 6	R/W	00000000 <sub>B</sub>
004C <sub>H</sub> to 004F <sub>H</sub>	—	(Disabled)	—	—
0050 <sub>H</sub>	—	(Disabled)	—	—
0051 <sub>H</sub>	—	(Disabled)	—	—
0052 <sub>H</sub>	—	(Disabled)	—	—
0053 <sub>H</sub>	—	(Disabled)	—	—
0054 <sub>H</sub>	—	(Disabled)	—	—
0055 <sub>H</sub>	—	(Disabled)	—	—
0056 <sub>H</sub> to 006B <sub>H</sub>	—	(Disabled)	—	—
006C <sub>H</sub>	ADC1	8/10-bit A/D converter control register 1	R/W	00000000 <sub>B</sub>
006D <sub>H</sub>	ADC2	8/10-bit A/D converter control register 2	R/W	00000000 <sub>B</sub>
006E <sub>H</sub>	ADDH	8/10-bit A/D converter data register (Upper)	R/W	00000000 <sub>B</sub>
006F <sub>H</sub>	ADDL	8/10-bit A/D converter data register (Lower)	R/W	00000000 <sub>B</sub>
0070 <sub>H</sub> to 0071 <sub>H</sub>	—	(Disabled)	—	—
0072 <sub>H</sub>	FSR	Flash memory status register	R/W	000X0000 <sub>B</sub>
0073 <sub>H</sub> to 0075 <sub>H</sub>	—	(Disabled)	—	—
0076 <sub>H</sub>	WREN	Wild register address compare enable register	R/W	00000000 <sub>B</sub>
0077 <sub>H</sub>	WROR	Wild register data test setting register	R/W	00000000 <sub>B</sub>
0078 <sub>H</sub>	—	Mirror of register bank pointer (RP) and direct bank pointer (DP)	—	—
0079 <sub>H</sub>	ILR0	Interrupt level setting register 0	R/W	11111111 <sub>B</sub>
007A <sub>H</sub>	ILR1	Interrupt level setting register 1	R/W	11111111 <sub>B</sub>
007B <sub>H</sub>	—	(Disabled)	—	—
007C <sub>H</sub>	—	(Disabled)	—	—
007D <sub>H</sub>	ILR4	Interrupt level setting register 4	R/W	11111111 <sub>B</sub>
007E <sub>H</sub>	ILR5	Interrupt level setting register 5	R/W	11111111 <sub>B</sub>
007F <sub>H</sub>	—	(Disabled)	—	—
0F80 <sub>H</sub>	WRARH0	Wild register address setting register (Upper) ch. 0	R/W	00000000 <sub>B</sub>
0F81 <sub>H</sub>	WRARL0	Wild register address setting register (Lower) ch. 0	R/W	00000000 <sub>B</sub>
0F82 <sub>H</sub>	WRDR0	Wild register data setting register ch. 0	R/W	00000000 <sub>B</sub>

(Continued)

# MB95200H/210H Series

Address	Register abbreviation	Register name	R/W	Initial value
0F83 <sub>H</sub>	WRARH1	Wild register address setting register (Upper) ch. 1	R/W	00000000 <sub>B</sub>
0F84 <sub>H</sub>	WRARL1	Wild register address setting register (Lower) ch. 1	R/W	00000000 <sub>B</sub>
0F85 <sub>H</sub>	WRDR1	Wild register data setting register ch. 1	R/W	00000000 <sub>B</sub>
0F86 <sub>H</sub>	WRARH2	Wild register address setting register (Upper) ch. 2	R/W	00000000 <sub>B</sub>
0F87 <sub>H</sub>	WRARL2	Wild register address setting register (Lower) ch. 2	R/W	00000000 <sub>B</sub>
0F88 <sub>H</sub>	WRDR2	Wild register data setting register ch. 2	R/W	00000000 <sub>B</sub>
0F89 <sub>H</sub> to 0F91 <sub>H</sub>	—	(Disabled)	—	—
0F92 <sub>H</sub>	T01CR0	8/16-bit composite timer 01 status control register 0 ch. 0	R/W	00000000 <sub>B</sub>
0F93 <sub>H</sub>	T00CR0	8/16-bit composite timer 00 status control register 0 ch. 0	R/W	00000000 <sub>B</sub>
0F94 <sub>H</sub>	T01DR	8/16-bit composite timer 01 data register ch. 0	R/W	00000000 <sub>B</sub>
0F95 <sub>H</sub>	T00DR	8/16-bit composite timer 00 data register ch. 0	R/W	00000000 <sub>B</sub>
0F96 <sub>H</sub>	TMCR0	8/16-bit composite timer 00/01 timer mode control register ch. 0	R/W	00000000 <sub>B</sub>
0F97 <sub>H</sub>	—	(Disabled)	—	—
0F98 <sub>H</sub>	—	(Disabled)	—	—
0F99 <sub>H</sub>	—	(Disabled)	—	—
0F9A <sub>H</sub>	—	(Disabled)	—	—
0F9B <sub>H</sub>	—	(Disabled)	—	—
0F9C <sub>H</sub> to 0FBB <sub>H</sub>	—	(Disabled)	—	—
0FBC <sub>H</sub>	—	(Disabled)	—	—
0FBD <sub>H</sub>	—	(Disabled)	—	—
0FBE <sub>H</sub> to 0FC2 <sub>H</sub>	—	(Disabled)	—	—
0FC3 <sub>H</sub>	AIDRL	A/D input disable register (Lower)	R/W	00000000 <sub>B</sub>
0FC4 <sub>H</sub> to 0FE3 <sub>H</sub>	—	(Disabled)	—	—
0FE4 <sub>H</sub>	CRTH	Main CR clock trimming register (Upper)	R/W	1XXXXXXX <sub>B</sub>
0FE5 <sub>H</sub>	CRTL	Main CR clock trimming register (Lower)	R/W	000XXXXX <sub>B</sub>
0FE6 <sub>H</sub> to 0FE7 <sub>H</sub>	—	(Disabled)	—	—
0FE8 <sub>H</sub>	SYSC	System configuration register	R/W	11000011 <sub>B</sub>

(Continued)



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Address	Register abbreviation	Register name	R/W	Initial value
0FE9 <sub>H</sub>	CMCR	Clock monitoring control register	R/W	XX000000 <sub>B</sub>
0FEA <sub>H</sub>	CMDR	Clock monitoring data register	R/W	00000000 <sub>B</sub>
0FEB <sub>H</sub>	WDTH	Watchdog timer selection ID register (Upper)	R/W	XXXXXXXX <sub>B</sub>
0FEC <sub>H</sub>	WDTL	Watchdog timer selection ID register (Lower)	R/W	XXXXXXXX <sub>B</sub>
0FED <sub>H</sub>	—	(Disabled)	—	—
0FEE <sub>H</sub>	ILSR	Input level select register	R/W	00000000 <sub>B</sub>
0FEF <sub>H</sub> to 0FFF <sub>H</sub>	—	(Disabled)	—	—

- R/W access symbols

R/W : Readable / Writable

R : Read only

W : Write only

- Initial value symbols

0 : The initial value of this bit is “0”.

1 : The initial value of this bit is “1”.

X : The initial value of this bit is undefined.

Note: Do not write to an address that is “(Disabled)”. If a “(Disabled)” address is read, an undefined value is returned.

# MB95200H/210H Series

## ■ INTERRUPT SOURCE TABLE (MB95200H Series)

Interrupt source	Interrupt request number	Vector table address		Bit name of interrupt level setting register	Priority order of interrupt sources of the same level (occurring simultaneously)
		Upper	Lower		
External interrupt ch. 4	IRQ0	FFFA <sub>H</sub>	FFFB <sub>H</sub>	L00 [1:0]	<div>High</div> <div>↑</div> <div>↓</div> <div>Low</div>
External interrupt ch. 5	IRQ1	FFF8 <sub>H</sub>	FFF9 <sub>H</sub>	L01 [1:0]	
External interrupt ch. 2	IRQ2	FFF6 <sub>H</sub>	FFF7 <sub>H</sub>	L02 [1:0]	
External interrupt ch. 6					
External interrupt ch. 3	IRQ3	FFF4 <sub>H</sub>	FFF5 <sub>H</sub>	L03 [1:0]	
External interrupt ch. 7					
—	IRQ4	FFF2 <sub>H</sub>	FFF3 <sub>H</sub>	L04 [1:0]	
8/16-bit composite timer ch. 0 (Lower)	IRQ5	FFF0 <sub>H</sub>	FFF1 <sub>H</sub>	L05 [1:0]	
8/16-bit composite timer ch. 0 (Upper)	IRQ6	FFEE <sub>H</sub>	FFEF <sub>H</sub>	L06 [1:0]	
LIN-UART (reception)	IRQ7	FFEC <sub>H</sub>	FFED <sub>H</sub>	L07 [1:0]	
LIN-UART (transmission)	IRQ8	FFEA <sub>H</sub>	FFEB <sub>H</sub>	L08 [1:0]	
—	IRQ9	FFE8 <sub>H</sub>	FFE9 <sub>H</sub>	L09 [1:0]	
—	IRQ10	FFE6 <sub>H</sub>	FFE7 <sub>H</sub>	L10 [1:0]	
—	IRQ11	FFE4 <sub>H</sub>	FFE5 <sub>H</sub>	L11 [1:0]	
—	IRQ12	FFE2 <sub>H</sub>	FFE3 <sub>H</sub>	L12 [1:0]	
—	IRQ13	FFE0 <sub>H</sub>	FFE1 <sub>H</sub>	L13 [1:0]	
8/16-bit composite timer ch. 1 (Upper)	IRQ14	FFDE <sub>H</sub>	FFDF <sub>H</sub>	L14 [1:0]	
—	IRQ15	FFDC <sub>H</sub>	FFDD <sub>H</sub>	L15 [1:0]	
—	IRQ16	FFDA <sub>H</sub>	FFDB <sub>H</sub>	L16 [1:0]	
—	IRQ17	FFD8 <sub>H</sub>	FFD9 <sub>H</sub>	L17 [1:0]	
8/10-bit A/D converter	IRQ18	FFD6 <sub>H</sub>	FFD7 <sub>H</sub>	L18 [1:0]	
Timebase timer	IRQ19	FFD4 <sub>H</sub>	FFD5 <sub>H</sub>	L19 [1:0]	
Watch prescaler	IRQ20	FFD2 <sub>H</sub>	FFD3 <sub>H</sub>	L20 [1:0]	
—	IRQ21	FFD0 <sub>H</sub>	FFD1 <sub>H</sub>	L21 [1:0]	
8/16-bit composite timer ch. 1 (Lower)	IRQ22	FFCE <sub>H</sub>	FFCF <sub>H</sub>	L22 [1:0]	
Flash memory	IRQ23	FFCC <sub>H</sub>	FFCD <sub>H</sub>	L23 [1:0]	

## ■ INTERRUPT SOURCE TABLE (MB95210H Series)

Interrupt source	Interrupt request number	Vector table address		Bit name of interrupt level setting register	Priority order of interrupt sources of the same level (occurring simultaneously)
		Upper	Lower		
External interrupt ch. 4	IRQ0	FFFA <sub>H</sub>	FFFB <sub>H</sub>	L00 [1:0]	<div>High</div> <div>↑</div> <div>↓</div> <div>Low</div>
—	IRQ1	FFF8 <sub>H</sub>	FFF9 <sub>H</sub>	L01 [1:0]	
—	IRQ2	FFF6 <sub>H</sub>	FFF7 <sub>H</sub>	L02 [1:0]	
External interrupt ch. 6					
—	IRQ3	FFF4 <sub>H</sub>	FFF5 <sub>H</sub>	L03 [1:0]	
—					
—	IRQ4	FFF2 <sub>H</sub>	FFF3 <sub>H</sub>	L04 [1:0]	
8/16-bit composite timer ch. 0 (Lower)	IRQ5	FFF0 <sub>H</sub>	FFF1 <sub>H</sub>	L05 [1:0]	
8/16-bit composite timer ch. 0 (Upper)	IRQ6	FFEE <sub>H</sub>	FFEF <sub>H</sub>	L06 [1:0]	
—	IRQ7	FFEC <sub>H</sub>	FFED <sub>H</sub>	L07 [1:0]	
—	IRQ8	FFEA <sub>H</sub>	FFEB <sub>H</sub>	L08 [1:0]	
—	IRQ9	FFE8 <sub>H</sub>	FFE9 <sub>H</sub>	L09 [1:0]	
—	IRQ10	FFE6 <sub>H</sub>	FFE7 <sub>H</sub>	L10 [1:0]	
—	IRQ11	FFE4 <sub>H</sub>	FFE5 <sub>H</sub>	L11 [1:0]	
—	IRQ12	FFE2 <sub>H</sub>	FFE3 <sub>H</sub>	L12 [1:0]	
—	IRQ13	FFE0 <sub>H</sub>	FFE1 <sub>H</sub>	L13 [1:0]	
—	IRQ14	FFDE <sub>H</sub>	FFDF <sub>H</sub>	L14 [1:0]	
—	IRQ15	FFDC <sub>H</sub>	FFDD <sub>H</sub>	L15 [1:0]	
—	IRQ16	FFDA <sub>H</sub>	FFDB <sub>H</sub>	L16 [1:0]	
—	IRQ17	FFD8 <sub>H</sub>	FFD9 <sub>H</sub>	L17 [1:0]	
8/10-bit A/D converter	IRQ18	FFD6 <sub>H</sub>	FFD7 <sub>H</sub>	L18 [1:0]	
Timebase timer	IRQ19	FFD4 <sub>H</sub>	FFD5 <sub>H</sub>	L19 [1:0]	
Watch prescaler	IRQ20	FFD2 <sub>H</sub>	FFD3 <sub>H</sub>	L20 [1:0]	
—	IRQ21	FFD0 <sub>H</sub>	FFD1 <sub>H</sub>	L21 [1:0]	
—	IRQ22	FFCE <sub>H</sub>	FFCF <sub>H</sub>	L22 [1:0]	
Flash memory	IRQ23	FFCC <sub>H</sub>	FFCD <sub>H</sub>	L23 [1:0]	

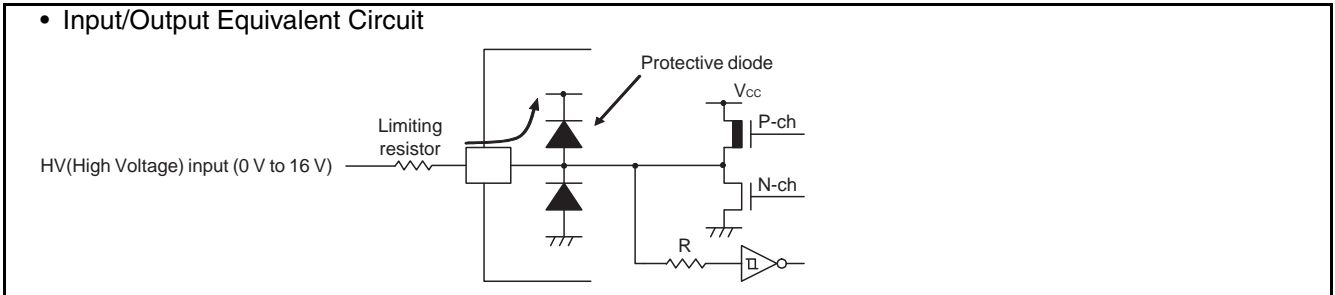
# MB95200H/210H Series

## ■ ELECTRICAL CHARACTERISTICS

### 1. Absolute Maximum Ratings

Parameter	Symbol	Rating		Unit	Remarks
		Min	Max		
Power supply voltage*1	$V_{CC}$	$V_{SS}-0.3$	$V_{SS}+6$	V	
Input voltage*1	$V_I$	$V_{SS}-0.3$	$V_{SS}+6$	V	*2
Output voltage*1	$V_O$	$V_{SS}-0.3$	$V_{SS}+6$	V	*2
Maximum clamp current	$I_{CLAMP}$	-2	+2	mA	Applicable to pins listed in *3
Total maximum clamp current	$\Sigma I_{CLAMP} $	—	20	mA	Applicable to pins listed in *3
“L” level maximum output current	$I_{OL1}$	—	15	mA	Other than P05, P06, P62 and P63*4
	$I_{OL2}$		15		P05, P06, P62 and P63*4
“L” level average current	$I_{OLAV1}$	—	4	mA	Other than P05, P06, P62 and P63*4 Average output current = operating current $\times$ operating ratio (1 pin)
	$I_{OLAV2}$		12		P05, P06, P62 and P63*4 Average output current = operating current $\times$ operating ratio (1 pin)
“L” level total maximum output current	$\Sigma I_{OL}$	—	100	mA	
“L” level total average output current	$\Sigma I_{OLAV}$	—	50	mA	Total average output current = operating current $\times$ operating ratio (Total number of pins)
“H” level maximum output current	$I_{OH1}$	—	-15	mA	Other than P05, P06, P62 and P63*4
	$I_{OH2}$		-15		P05, P06, P62 and P63*4
“H” level average current	$I_{OHAV1}$	—	-4	mA	Other than P05, P06, P62 and P63*4 Average output current = operating current $\times$ operating ratio (1 pin)
	$I_{OHAV2}$		-8		P05, P06, P62 and P63*4 Average output current = operating current $\times$ operating ratio (1 pin)
“H” level total maximum output current	$\Sigma I_{OH}$	—	-100	mA	
“H” level total average output current	$\Sigma I_{OHAV}$	—	-50	mA	Total average output current = operating current $\times$ operating ratio (Total number of pins)
Power consumption	$P_d$	—	320	mW	
Operating temperature	$T_A$	-40	+85	°C	
Storage temperature	$T_{stg}$	-55	+150	°C	

- \*1: The parameter is based on  $V_{SS} = 0.0 \text{ V}$ .
- \*2:  $V_I$  and  $V_O$  must not exceed  $V_{CC}+0.3 \text{ V}$ .  $V_I$  must not exceed the rated voltage. However, if the maximum current to/from an input is limited by means of an external component, the  $I_{CLAMP}$  rating is used instead of the  $V_I$  rating.
- \*3: Applicable to the following pins: P00 to P07, P62 to P64, PG1, PG2, PF0, PF1 (P00 to P03, P07, P62 to P64, PG1, PG2, PF0 and PF1 are available in MB95F204H/F203H/F202H/F204K/F203K/F202K.)
- Use under recommended operating conditions.
  - Use with DC voltage (current).
  - The HV (High Voltage) signal is an input signal exceeding the  $V_{CC}$  voltage. Always connect a limiting resistor between the HV (High Voltage) signal and the microcontroller before applying the HV (High Voltage) signal.
  - The value of the limiting resistor should be set to a value at which the current to be input to the microcontroller pin when the HV (High Voltage) signal is input is below the standard value, irrespective of whether the current is transient current or stationary current.
  - When the microcontroller drive current is low, such as in low power consumption modes, the HV (High Voltage) input potential may pass through the protective diode to increase the potential of the  $V_{CC}$  pin, affecting other devices.
  - If the HV (High Voltage) signal is input when the microcontroller power supply is off (not fixed at 0 V), since power is supplied from the pins, incomplete operations may be executed.
  - If the HV (High Voltage) input is input after power-on, since power is supplied from the pins, the voltage of power supply may not be sufficient to enable a power-on reset.
  - Do not leave the HV (High Voltage) input pin unconnected.
  - Example of a recommended circuit:
- Input/Output Equivalent Circuit



- \*4: P62 and P63 are available in MB95F204H/F203H/F202H/F204K/F203K/F202K.

**WARNING:** A semiconductor device may be damaged by applying stress (voltage, current, temperature, etc.) in excess of the absolute maximum rating. Therefore, ensure that not a single parameter exceeds its absolute maximum rating.

# MB95200H/210H Series

## 2. Recommended Operating Conditions

(V<sub>SS</sub>=0.0 V)

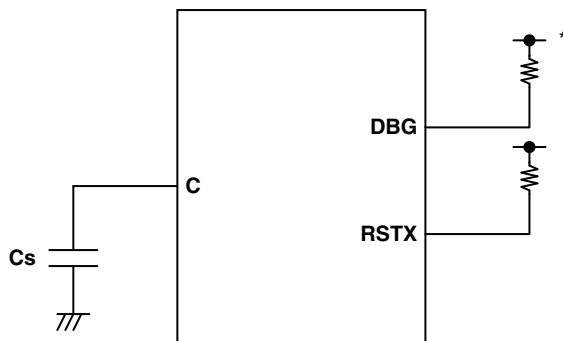
Parameter	Symbol	Value		Unit	Remarks	
		Min	Max			
Power supply voltage	V <sub>CC</sub>	2.4*1*2	5.5*1	V	In normal operation	Other than on-chip debug mode
		2.3	5.5		Hold condition in stop mode	
		2.9	5.5		In normal operation	On-chip debug mode
		2.3	5.5		Hold condition in stop mode	
Smoothing capacitor	C <sub>S</sub>	0.022	1	μF	*3	
Operating temperature	T <sub>A</sub>	-40	+85	°C	Other than on-chip debug function	
		+5	+35		On-chip debug function	

\*1: The value varies depending on the operating frequency, the machine clock and the analog guaranteed range.

\*2: The value is 2.88 V when the low-voltage detection reset is used.

\*3: Use a ceramic capacitor or a capacitor with equivalent frequency characteristics. The bypass capacitor for the V<sub>CC</sub> pin must have a capacitance larger than C<sub>S</sub>. For the connection to a smoothing capacitor C<sub>S</sub>, see the diagram below. To prevent the device from unintentionally entering an unknown mode due to noise, minimize the distance between the C pin and C<sub>S</sub> and the distance between C<sub>S</sub> and the V<sub>SS</sub> pin when designing the layout of a printed circuit board.

### ● DBG / RSTX / C pin connection diagram



\*: Since the DBG pin becomes a communication pin in on-chip debug mode, set a pull-up resistor value suiting the input/output specifications of P12/DBG.

**WARNING:** The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the electrical characteristics of the device are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact sales representatives beforehand.

## 3. DC Characteristics

( $V_{CC} = 5.0\text{ V} \pm 10\%$ ,  $V_{SS} = 0.0\text{ V}$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ )

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min	Typ	Max		
"H" level input voltage	$V_{IH1}$	P04	*1	$0.7 V_{CC}$	—	$V_{CC}+0.3$	V	When CMOS input level (hysteresis input) is selected
	$V_{IHS}$	P00 to P07, P12, P62 to P64, PF0 to PF1, PG1 to PG2	*1	$0.8 V_{CC}$	—	$V_{CC}+0.3$	V	Hysteresis input
	$V_{IHM}$	PF2	—	$0.7 V_{CC}$	—	$V_{CC}+0.3$	V	Hysteresis input
"L" level input voltage	$V_{IL}$	P04	*1	$V_{SS}-0.3$	—	$0.3 V_{CC}$	V	When CMOS input level (hysteresis input) is selected
	$V_{ILS}$	P00 to P07, P12, P62 to P64, PF0 to PF1, PG1 to PG2	*1	$V_{SS}-0.3$	—	$0.2 V_{CC}$	V	Hysteresis input
	$V_{ILM}$	PF2	—	$V_{SS}-0.3$	—	$0.3 V_{CC}$	V	Hysteresis input
Open-drain output application voltage	$V_D$	PF2, P12	—	$V_{SS}-0.3$	—	$0.2 V_{CC}$	V	
"H" level output voltage	$V_{OH1}$	Output pins other than P05, P06, P62, P63, PF2 and P12 <sup>*2</sup>	$I_{OH} = -4\text{ mA}$	$V_{CC}-0.5$	—	—	V	
	$V_{OH2}$	P05, P06, P62, P63 <sup>*2</sup>	$I_{OH} = -8\text{ mA}$	$V_{CC}-0.5$	—	—	V	
"L" level output voltage	$V_{OL1}$	Output pins other than P05, P06, P62 and P63 <sup>*2</sup>	$I_{OL} = 4\text{ mA}$	—	—	0.4	V	
	$V_{OL2}$	P05, P06, P62, P63 <sup>*2</sup>	$I_{OL} = 2\text{ mA}$	—	—	0.4	V	
Input leak current (Hi-Z output leak current)	$I_{LI}$	All input pins	$0.0\text{ V} < V_I < V_{CC}$	-5	—	+5	$\mu\text{A}$	When pull-up resistance is disabled
Pull-up resistance	$R_{PULL}$	P00 to P07, PG1, PG2 <sup>*3</sup>	$V_I = 0\text{ V}$	25	50	100	k $\Omega$	When pull-up resistance is enabled

(Continued)

# MB95200H/210H Series

( $V_{CC} = 5.0\text{ V} \pm 10\%$ ,  $V_{SS} = 0.0\text{ V}$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ )

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min	Typ	Max		
Input capacitance	$C_{IN}$	Other than $V_{CC}$ and $V_{SS}$	$f = 1\text{ MHz}$	—	5	15	pF	
Power supply current*4	$I_{CC}$	$V_{CC}$ (External clock operation)	$V_{CC} = 5.5\text{ V}$ $F_{CH} = 32\text{ MHz}$ $F_{MP} = 16\text{ MHz}$ Main clock mode (divided by 2)	—	13	17	mA	Flash memory product (except writing and erasing)
				—	33.5	39.5	mA	Flash memory product (at writing and erasing)
				—	15	21	mA	At A/D conversion
	$I_{CCS}$		$V_{CC} = 5.5\text{ V}$ $F_{CH} = 32\text{ MHz}$ $F_{MP} = 16\text{ MHz}$ Main sleep mode (divided by 2)	—	5.5	9	mA	
	$I_{CCL}$		$V_{CC} = 5.5\text{ V}$ $F_{CL} = 32\text{ kHz}$ $F_{MPL} = 16\text{ kHz}$ Subclock mode (divided by 2) $T_A = +25^\circ\text{C}$	—	65	153	$\mu\text{A}$	
	$I_{CCLS}$		$V_{CC} = 5.5\text{ V}$ $F_{CL} = 32\text{ kHz}$ $F_{MPL} = 16\text{ kHz}$ Subsleep mode (divided by 2) $T_A = +25^\circ\text{C}$	—	10	84	$\mu\text{A}$	
	$I_{CCT}$		$V_{CC} = 5.5\text{ V}$ $F_{CL} = 32\text{ kHz}$ Watch mode Main stop mode $T_A = +25^\circ\text{C}$	—	5	30	$\mu\text{A}$	

(Continued)



# MB95200H/210H Series

( $V_{CC} = 5.0\text{ V} \pm 10\%$ ,  $V_{SS} = 0.0\text{ V}$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ )

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min	Typ	Max		
Power supply current*4	$I_{CCMCR}$	$V_{CC}$	$V_{CC} = 5.5\text{ V}$ $F_{CRH} = 10\text{ MHz}$ $F_{MP} = 10\text{ MHz}$ Main CR clock mode	—	8.6	—	mA	
	$I_{CCSCR}$		$V_{CC} = 5.5\text{ V}$ Sub-CR clock mode (divided by 2) $T_A = +25^\circ\text{C}$	—	110	410	$\mu\text{A}$	
	$I_{CCTS}$	$V_{CC}$ (External clock operation)	$V_{CC} = 5.5\text{ V}$ $F_{CH} = 32\text{ MHz}$ Timebase timer mode $T_A = +25^\circ\text{C}$	—	1.1	3	mA	
	$I_{CCH}$		$V_{CC} = 5.5\text{ V}$ Substop mode $T_A = +25^\circ\text{C}$	—	3.5	22.5	$\mu\text{A}$	Main stop mode for single clock selection
	$I_{LVD}$	$V_{CC}$	Current consumption for low-voltage detection circuit only	—	37	54	$\mu\text{A}$	
	$I_{CRH}$		Current consumption for the internal main CR oscillator	—	0.5	0.6	mA	
	$I_{CRL}$		Current consumption for the internal sub-CR oscillator oscillating at 100 kHz	—	20	72	$\mu\text{A}$	

\*1: The input level of P04 can be switched between “CMOS input level” and “hysteresis input level”. The input level selection register (ILSR) is used to switch between the two input levels.

\*2: P62 and P63 are available in MB95F204H/F203H/F202H/F204K/F203K/F202K.

\*3: P00 to P03, P07, PG1 and PG2 are available in MB95F204H/F203H/F202H/F204K/F203K/F202K.

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- \*4: • The power supply current is determined by the external clock. When the low-voltage detection option is selected, the power-supply current will be the sum of adding the current consumption of the low-voltage detection circuit ( $I_{LVD}$ ) to a specified value. In addition, when both the low-voltage detection option and the internal CR oscillator are selected, the power supply current will be the sum of adding up the current consumption of the low-voltage detection circuit, the current consumption of the internal CR oscillators ( $I_{CRH}$ ,  $I_{CRL}$ ) and a specified value. In on-chip debug mode, the internal CR oscillator ( $I_{CRH}$ ) and the low-voltage detection circuit are always enabled, and current consumption therefore increases accordingly.
- See "4. AC Characteristics: (1) Clock Timing" for  $F_{CH}$  and  $F_{CL}$ .
- See "4. AC Characteristics: (2) Source Clock/Machine Clock" for  $F_{MP}$  and  $F_{MPL}$ .

## 4. AC Characteristics

### (1) Clock Timing

( $V_{CC} = 2.4 \text{ V to } 5.5 \text{ V}$ ,  $V_{SS} = 0.0 \text{ V}$ ,  $T_A = -40^\circ\text{C to } +85^\circ\text{C}$ )

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min	Typ	Max		
Clock frequency	$F_{CH}$	X0, X1	—	1	—	16.25	MHz	When the main oscillation circuit is used
		X0, HCLK1, HCLK2	X1 open	1	—	12	MHz	When the main external clock is used
		X0, X1, HCLK1, HCLK2	—	1	—	32.5	MHz	
	$F_{CRH}$	—	—	9.7	10	10.3	MHz	When the main internal clock is used $3.3 \text{ V} \leq V_{CC} \leq 5.5 \text{ V} (-40^\circ\text{C} \leq T_A \leq 40^\circ\text{C})$ $2.4 \text{ V} \leq V_{CC} < 3.3 \text{ V} (0^\circ\text{C} \leq T_A \leq 40^\circ\text{C})$
				7.76	8	8.24	MHz	
				0.97	1	1.03	MHz	
				9.55	10	10.45	MHz	When the main internal clock is used $3.3 \text{ V} \leq V_{CC} \leq 5.5 \text{ V} (40^\circ\text{C} < T_A \leq 85^\circ\text{C})$
				7.64	8	8.36	MHz	
				0.955	1	1.045	MHz	
				9.5	10	10.5	MHz	When the main internal clock is used $2.4 \text{ V} \leq V_{CC} < 3.3 \text{ V}$ $(-40^\circ\text{C} \leq T_A < 0^\circ\text{C}, 40^\circ\text{C} < T_A \leq 85^\circ\text{C})$
				7.6	8	8.4	MHz	
				0.95	1	1.05	MHz	
	$F_{CL}$	X0A, X1A	—	—	32.768	—	kHz	When the main oscillation circuit is used
				—	32.768	—	kHz	When the sub-external clock is used
	$F_{CRL}$	—	—	50	100	200	kHz	When the sub-internal CR clock is used
Clock cycle time	$t_{HCYL}$	X0, X1	—	61.5	—	1000	ns	When the main oscillation circuit is used
		X0, HCLK1, HCLK2	X1 open	83.4	—	1000	ns	When the external clock is used
		X0, X1, HCLK1, HCLK2	—	30.8	—	1000	ns	
	$t_{LCYL}$	X0A, X1A	—	—	30.5	—	$\mu\text{s}$	When the subclock is used

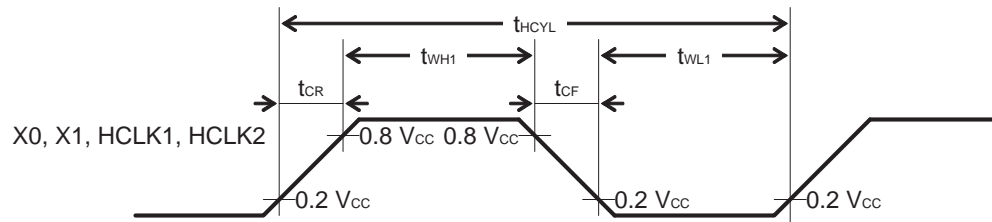
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# MB95200H/210H Series

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( $V_{CC} = 2.4 \text{ V}$  to  $5.5 \text{ V}$ ,  $V_{SS} = 0.0 \text{ V}$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ )

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min	Typ	Max		
Input clock pulse width	$t_{WH1}$ $t_{WL1}$	X0, HCLK1, HCLK2	X1 open	33.4	—	—	ns	When the external clock is used, the duty ratio should range between 40% and 60%.
		X0, X1, HCLK1, HCLK2	—	12.4	—	—	ns	
	$t_{WH2}$ $t_{WL2}$	X0A	—	—	15.2	—	$\mu\text{s}$	
Input clock rise time and fall time	$t_{CR}$ $t_{CF}$	X0, HCLK1, HCLK2	X1 open	—	—	5	ns	When the external clock is used
		X0, X1 HCLK1, HCLK2	—	—	—	5	ns	
Internal CR oscillation start time	$t_{CRHWK}$	—	—	—	—	80	$\mu\text{s}$	When the main internal CR clock is used
	$t_{CRLWK}$	—	—	—	—	10	$\mu\text{s}$	When the sub-internal CR clock is used

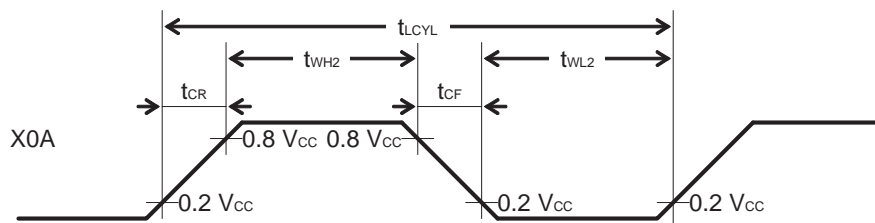
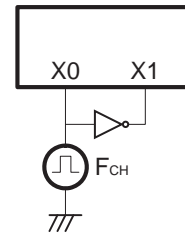
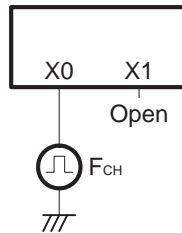
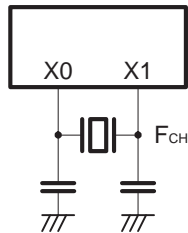


- Figure of main clock input port external connection

When a crystal oscillator or a ceramic oscillator is used

When the external clock is used (X1 is open)

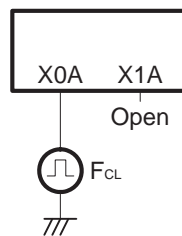
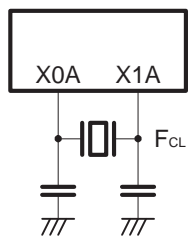
When the external clock is used (X0 is open)



- Figure of subclock input port external connection

When a crystal oscillator or a ceramic oscillator is used

When the external clock is used



# MB95200H/210H Series

## (2) Source Clock/Machine Clock

( $V_{CC} = 5.0 \text{ V} \pm 10\%$ ,  $V_{SS} = 0.0 \text{ V}$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ )

Parameter	Symbol	Pin name	Value			Unit	Remarks
			Min	Typ	Max		
Source clock cycle time* <sup>1</sup> (clock before division)	t <sub>SCLK</sub>	—	61.5	—	2000	ns	When the main external clock is used Min: F <sub>CH</sub> = 32.5 MHz, divided by 2 Max: F <sub>CH</sub> = 1 MHz, divided by 2
			100	—	1000	ns	When the main CR clock is used Min: F <sub>CRH</sub> = 10 MHz Max: F <sub>CRH</sub> = 1 MHz
			—	61	—	μs	When the sub-oscillation clock is used F <sub>CL</sub> = 32.768 kHz, divided by 2
			—	20	—	μs	When the sub-oscillation clock is used F <sub>CRL</sub> = 100 kHz, divided by 2
Source clock frequency	F <sub>SP</sub>	—	0.5	—	16.25	MHz	When the main oscillation clock is used
			1	—	10	MHz	When the main CR clock is used
	F <sub>SPL</sub>		—	16.384	—	kHz	When the sub-oscillation clock is used
			—	50	—	kHz	When the sub-CR clock is used F <sub>CRL</sub> = 100 kHz, divided by 2
Machine clock cycle time* <sup>2</sup> (minimum instruction execution time)	t <sub>MCLK</sub>	—	61.5	—	32000	ns	When the main oscillation clock is used Min: F <sub>SP</sub> = 16.25 MHz, no division Max: F <sub>SP</sub> = 0.5 MHz, divided by 16
			100	—	16000	ns	When the main CR clock is used Min: F <sub>SP</sub> = 10 MHz Max: F <sub>SP</sub> = 1 MHz, divided by 16
			61	—	976.5	μs	When the sub-oscillation clock is used Min: F <sub>SPL</sub> = 16.384 kHz, no division Max: F <sub>SPL</sub> = 16.384 kHz, divided by 16
			20	—	320	μs	When the sub-CR clock is used Min: F <sub>SPL</sub> = 50 kHz, no division Max: F <sub>SPL</sub> = 50 kHz, divided by 16
Machine clock frequency	F <sub>MP</sub>	—	0.031	—	16.25	MHz	When the main oscillation clock is used
			0.0625	—	10	MHz	When the main CR clock is used
	F <sub>MPL</sub>		1.024	—	16.384	kHz	When the sub-oscillation clock is used
			3.125	—	50	kHz	When the sub-CR clock is used F <sub>CRL</sub> = 100 kHz

\*1: This is the clock before it is divided according to the division ratio set by the machine clock division ratio selection bits (SYCC : DIV1 and DIV0) . This source clock is divided to become a machine clock according to the division ratio set by the machine clock division ratio selection bits (SYCC : DIV1 and DIV0) . In addition, a source clock can be selected from the following.

- Main clock divided by 2
- Main CR clock
- Subclock divided by 2
- Sub-CR clock divided by 2

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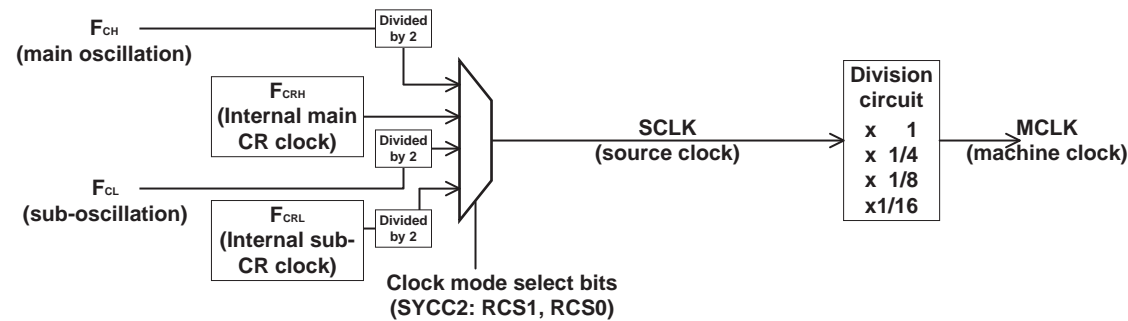
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\*2: This is the operating clock of the microcontroller. A machine clock can be selected from the following.

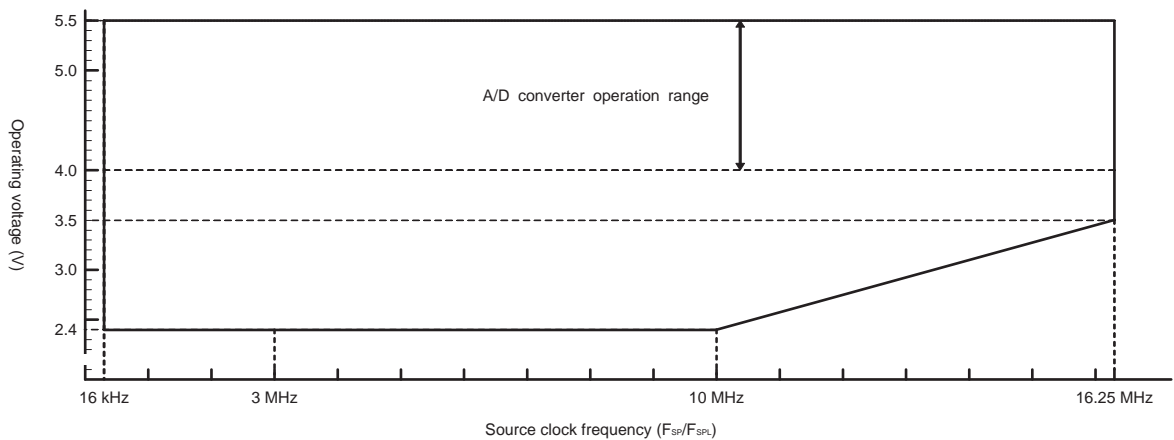
- Source clock (no division)
- Source clock divided by 4
- Source clock divided by 8
- Source clock divided by 16

# MB95200H/210H Series

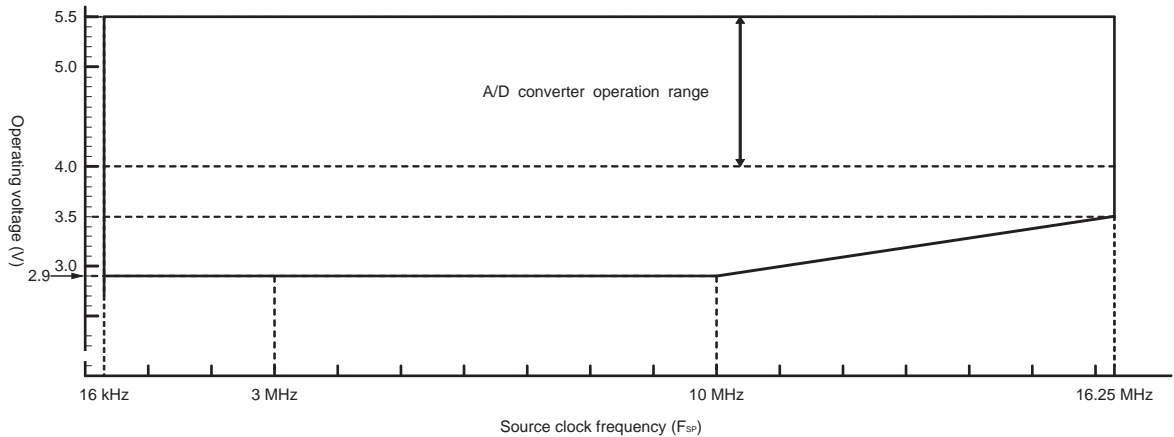
- Schematic diagram of the clock generation block



- Operating voltage - Operating frequency (When  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ )  
➤ MB95200H/210H (without the on-chip debug function)



- Operating voltage - Operating frequency (When  $T_A = +5^\circ\text{C}$  to  $+35^\circ\text{C}$ )  
➤ MB95200H/210H (with the on-chip debug function)





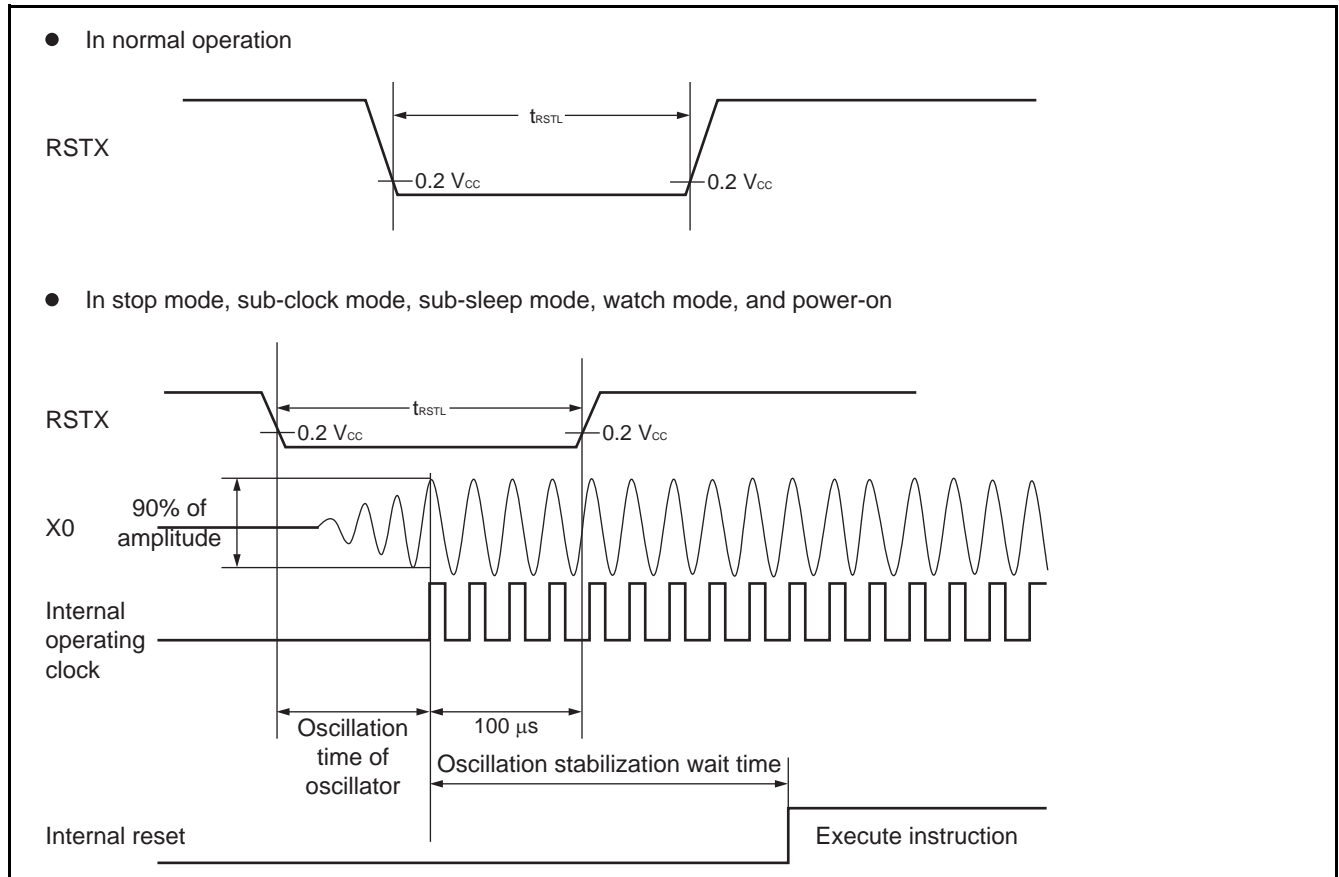
## (3) External Reset

( $V_{CC} = 5.0 \text{ V} \pm 10\%$ ,  $V_{SS} = 0.0 \text{ V}$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ )

Parameter	Symbol	Value		Unit	Remarks
		Min	Max		
RSTX "L" level pulse width	$t_{RSTL}$	$2 t_{MCLK}^{*1}$	—	ns	In normal operation
		Oscillation time of the oscillator <sup>*2</sup> +100	—	$\mu\text{s}$	In stop mode, subclock mode, sub-sleep mode, and watch mode
		100	—	$\mu\text{s}$	In timebase timer mode

\*1: See "(2) Source Clock/Machine Clock" for  $t_{MCLK}$ .

\*2: The oscillation time of an oscillator is the time that the amplitude reaches 90%. The crystal oscillator has an oscillation time of between several ms and tens of ms. The ceramic oscillator has an oscillation time of between hundreds of  $\mu\text{s}$  and several ms. The external clock has an oscillation time of 0 ms. The CR oscillator clock has an oscillation time of between several  $\mu\text{s}$  and several ms.

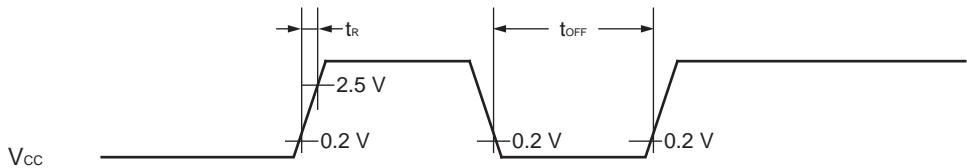


# MB95200H/210H Series

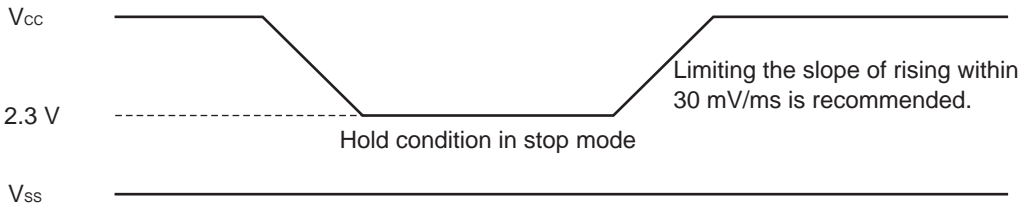
## (4) Power-on Reset

( $V_{SS} = 0.0\text{ V}$ ,  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ )

Parameter	Symbol	Condition	Value		Unit	Remarks
			Min	Max		
Power supply rising time	$t_R$	—	—	50	ms	
Power supply cutoff time	$t_{OFF}$	—	1	—	ms	Wait time until power-on



Note: A sudden change of power supply voltage may activate the power-on reset function. When changing the power supply voltage during the operation, set the slope of rising to within 30 mV/ms as shown below.



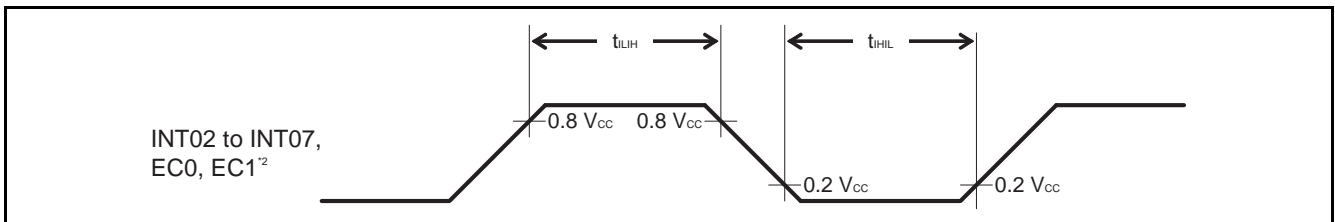
## (5) Peripheral Input Timing

( $V_{CC} = 5.0\text{ V} \pm 10\%$ ,  $V_{SS} = 0.0\text{ V}$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ )

Parameter	Symbol	Pin name	Value		Unit
			Min	Max	
Peripheral input "H" pulse width	$t_{\text{LIH}}$	INT02 to INT07, EC0, EC1 <sup>*2</sup>	$2\ t_{\text{MCLK}}^{*1}$	—	ns
Peripheral input "L" pulse width	$t_{\text{HIL}}$		$2\ t_{\text{MCLK}}^{*1}$	—	ns

\*1: See "(2) Source Clock/Machine Clock" for  $t_{\text{MCLK}}$ .

\*2: INT02, INT03, INT05, INT07 and EC1 are available in MB95F204H/F203H/F202H/F204K/F203K/F202K.



# MB95200H/210H Series

## (6) LIN-UART Timing (Available in MB95F204H/F203H/F202H/F204K/F203K/F202K only)

Sampling is executed at the rising edge of the sampling clock<sup>\*1</sup>, and serial clock delay is disabled<sup>\*2</sup>.  
(ESCR register : SCES bit = 0, ECCR register : SCDE bit = 0)

(V<sub>CC</sub> = 5.0 V±10%, AV<sub>SS</sub> = V<sub>SS</sub> = 0.0 V, T<sub>A</sub> = -40°C to +85°C)

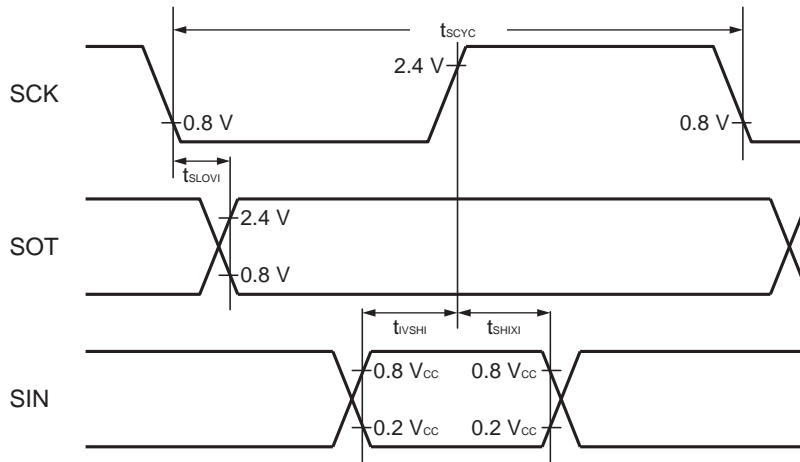
Parameter	Symbol	Pin name	Condition	Value		Unit
				Min	Max	
Serial clock cycle time	t <sub>SCYC</sub>	SCK	Internal clock operation output pin: C <sub>L</sub> = 80 pF+1 TTL	5 t <sub>MCLK</sub> <sup>*3</sup>	—	ns
SCK ↓→ SOT delay time	t <sub>SLOVI</sub>	SCK, SOT		-95	+95	ns
Valid SIN → SCK ↑	t <sub>IVSHI</sub>	SCK, SIN		t <sub>MCLK</sub> <sup>*3</sup> +190	—	ns
SCK ↑→ valid SIN hold time	t <sub>SHIXI</sub>	SCK, SIN		0	—	ns
Serial clock “L” pulse width	t <sub>SLSH</sub>	SCK	External clock operation output pin: C <sub>L</sub> = 80 pF+1 TTL	3 t <sub>MCLK</sub> <sup>*3</sup> -t <sub>R</sub>	—	ns
Serial clock “H” pulse width	t <sub>SHSL</sub>	SCK		t <sub>MCLK</sub> <sup>*3</sup> +95	—	ns
SCK ↓→ SOT delay time	t <sub>SLOVE</sub>	SCK, SOT		—	2 t <sub>MCLK</sub> <sup>*3</sup> +95	ns
Valid SIN → SCK ↑	t <sub>IVSHE</sub>	SCK, SIN		190	—	ns
SCK ↑→ valid SIN hold time	t <sub>SHIXE</sub>	SCK, SIN		t <sub>MCLK</sub> <sup>*3</sup> +95	—	ns
SCK fall time	t <sub>F</sub>	SCK		—	10	ns
SCK rise time	t <sub>R</sub>	SCK		—	10	ns

\*1: There is a function used to choose whether the sampling of reception data is performed at a rising edge or a falling edge of the serial clock.

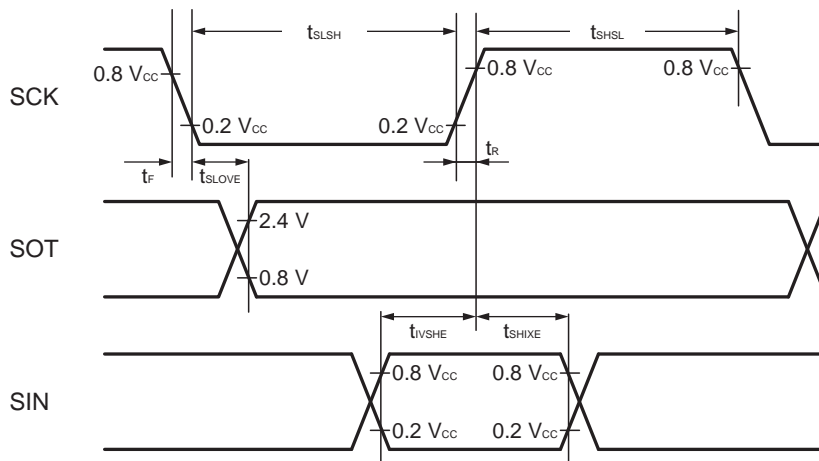
\*2: The serial clock delay function is a function used to delay the output signal of the serial clock for half the clock.

\*3: See “(2) Source Clock/Machine Clock” for t<sub>MCLK</sub>.

● Internal shift clock mode



● External shift clock mode



# MB95200H/210H Series

Sampling is executed at the falling edge of the sampling clock<sup>\*1</sup>, and serial clock delay is disabled<sup>\*2</sup>.  
(ESCR register : SCES bit = 1, ECCR register : SCDE bit = 0)

(V<sub>CC</sub> = 5.0 V $\pm$ 10%, V<sub>SS</sub> = 0.0 V, T<sub>A</sub> = -40°C to +85°C)

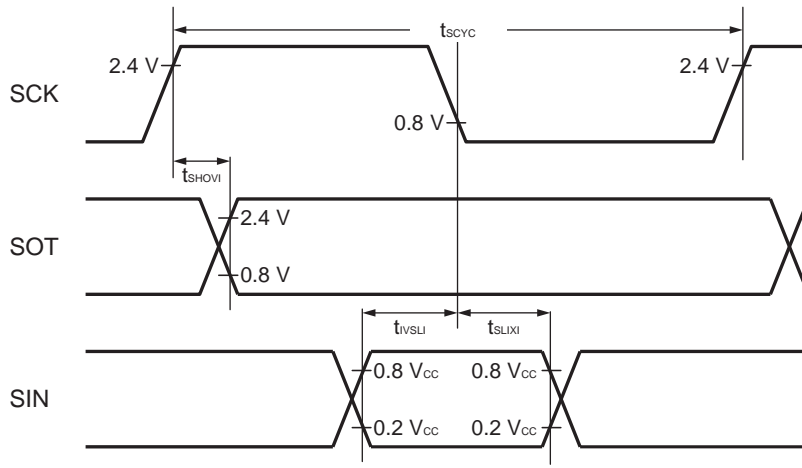
Parameter	Symbol	Pin name	Condition	Value		Unit
				Min	Max	
Serial clock cycle time	t <sub>SCYC</sub>	SCK	Internal clock operation output pin: C <sub>L</sub> = 80 pF+1 TTL	5 t <sub>MCLK</sub> <sup>*3</sup>	—	ns
SCK $\uparrow \rightarrow$ SOT delay time	t <sub>SHOVI</sub>	SCK, SOT		-95	+95	ns
Valid SIN $\rightarrow$ SCK $\downarrow$	t <sub>IVSLI</sub>	SCK, SIN		t <sub>MCLK</sub> <sup>*3</sup> +190	—	ns
SCK $\downarrow \rightarrow$ valid SIN hold time	t <sub>SLIXI</sub>	SCK, SIN		0	—	ns
Serial clock “H” pulse width	t <sub>SHSL</sub>	SCK	External clock operation output pin: C <sub>L</sub> = 80 pF+1 TTL	3 t <sub>MCLK</sub> <sup>*3</sup> -t <sub>R</sub>	—	ns
Serial clock “L” pulse width	t <sub>SLSH</sub>	SCK		t <sub>MCLK</sub> <sup>*3</sup> +95	—	ns
SCK $\uparrow \rightarrow$ SOT delay time	t <sub>SHOVE</sub>	SCK, SOT		—	2 t <sub>MCLK</sub> <sup>*3</sup> +95	ns
Valid SIN $\rightarrow$ SCK $\downarrow$	t <sub>IVSLE</sub>	SCK, SIN		190	—	ns
SCK $\downarrow \rightarrow$ valid SIN hold time	t <sub>SLIXE</sub>	SCK, SIN		t <sub>MCLK</sub> <sup>*3</sup> +95	—	ns
SCK fall time	t <sub>F</sub>	SCK		—	10	ns
SCK rise time	t <sub>R</sub>	SCK		—	10	ns

\*1: There is a function used to choose whether the sampling of reception data is performed at a rising edge or a falling edge of the serial clock.

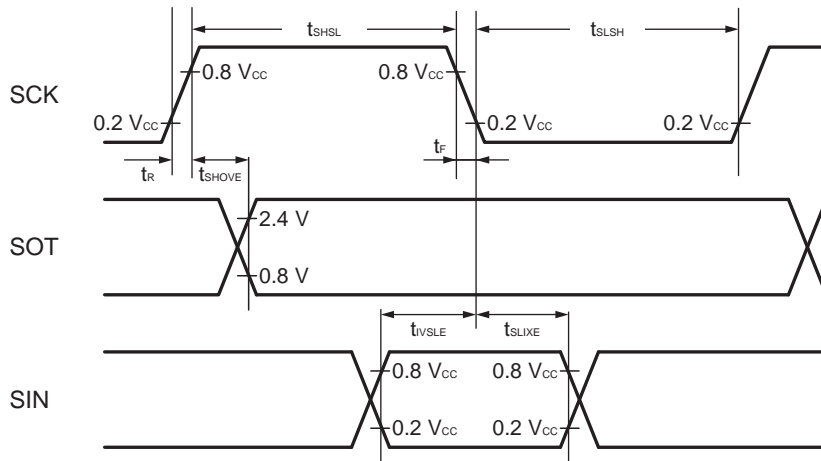
\*2: The serial clock delay function is a function used to delay the output signal of the serial clock for half the clock.

\*3: See “(2) Source Clock/Machine Clock” for t<sub>MCLK</sub>.

● Internal shift clock mode



● External shift clock mode



# MB95200H/210H Series

Sampling is executed at the rising edge of the sampling clock<sup>\*1</sup>, and serial clock delay is enabled<sup>\*2</sup>.  
(ESCR register : SCES bit = 0, ECCR register : SCDE bit = 1)

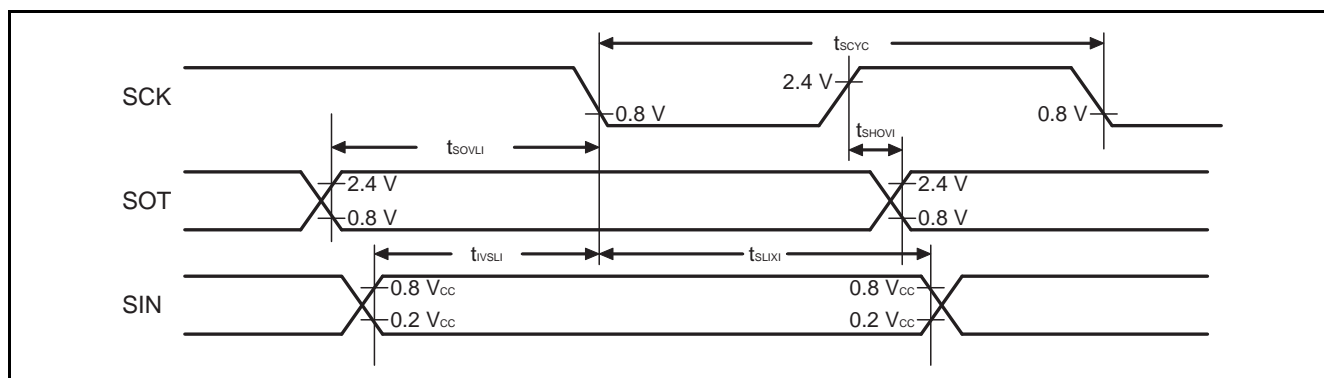
( $V_{CC} = 5.0\text{ V} \pm 10\%$ ,  $V_{SS} = 0.0\text{ V}$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ )

Parameter	Symbol	Pin name	Condition	Value		Unit
				Min	Max	
Serial clock cycle time	$t_{SCYC}$	SCK	Internal clock operation output pin: $C_L = 80\text{ pF} + 1\text{ TTL}$	$5\ t_{MCLK}^{*3}$	—	ns
SCK $\uparrow \rightarrow$ SOT delay time	$t_{SHOVI}$	SCK, SOT		-95	+95	ns
Valid SIN $\rightarrow$ SCK $\downarrow$	$t_{IVSLI}$	SCK, SIN		$t_{MCLK}^{*3} + 190$	—	ns
SCK $\downarrow \rightarrow$ valid SIN hold time	$t_{SLIXI}$	SCK, SIN		0	—	ns
SOT $\rightarrow$ SCK $\downarrow$ delay time	$t_{SOVLI}$	SCK, SOT		—	$4\ t_{MCLK}^{*3}$	ns

\*1: There is a function used to choose whether the sampling of reception data is performed at a rising edge or a falling edge of the serial clock.

\*2: The serial clock delay function is a function that delays the output signal of the serial clock for half clock.

\*3: See "(2) Source Clock/Machine Clock" for  $t_{MCLK}$ .





Sampling is executed at the falling edge of the sampling clock\*<sup>1</sup>, and serial clock delay is enabled\*<sup>2</sup>.  
(ESCR register : SCES bit = 1, ECCR register : SCDE bit = 1)

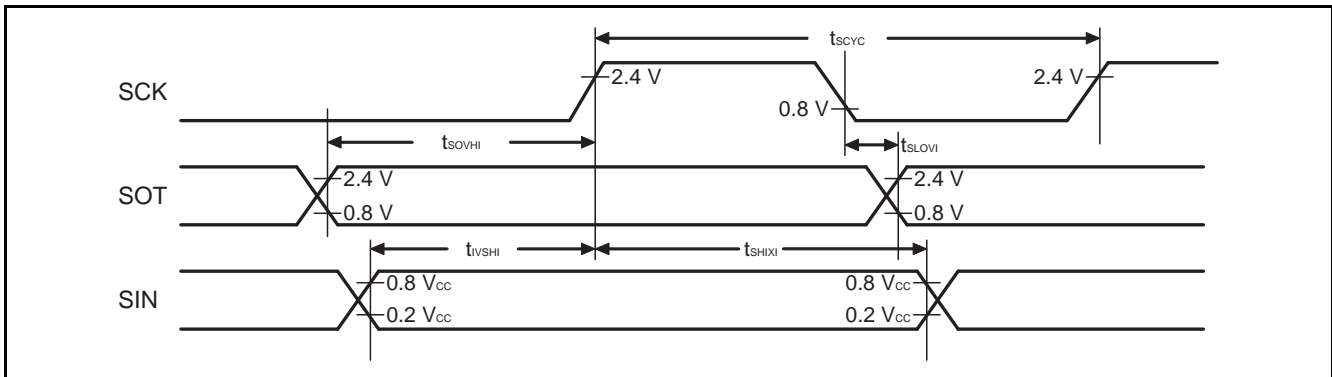
( $V_{CC} = 5.0\text{ V} \pm 10\%$ ,  $V_{SS} = 0.0\text{ V}$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ )

Parameter	Symbol	Pin name	Condition	Value		Unit
				Min	Max	
Serial clock cycle time	$t_{SCYC}$	SCK	Internal clock operation output pin: $C_L = 80\text{ pF} + 1\text{ TTL}$	$5\ t_{MCLK}^{*3}$	—	ns
SCK $\downarrow \rightarrow$ SOT delay time	$t_{SLOVI}$	SCK, SOT		-95	+95	ns
Valid SIN $\rightarrow$ SCK $\uparrow$	$t_{IVSHI}$	SCK, SIN		$t_{MCLK}^{*3} + 190$	—	ns
SCK $\uparrow \rightarrow$ valid SIN hold time	$t_{SHIXI}$	SCK, SIN		0	—	ns
SOT $\rightarrow$ SCK $\uparrow$ delay time	$t_{SOVHI}$	SCK, SOT		—	$4\ t_{MCLK}^{*3}$	ns

\*1: There is a function used to choose whether the sampling of reception data is performed at a rising edge or a falling edge of the serial clock.

\*2: The serial clock delay function is a function that delays the output signal of the serial clock for half clock.

\*3: See “(2) Source Clock/Machine Clock” for  $t_{MCLK}$ .

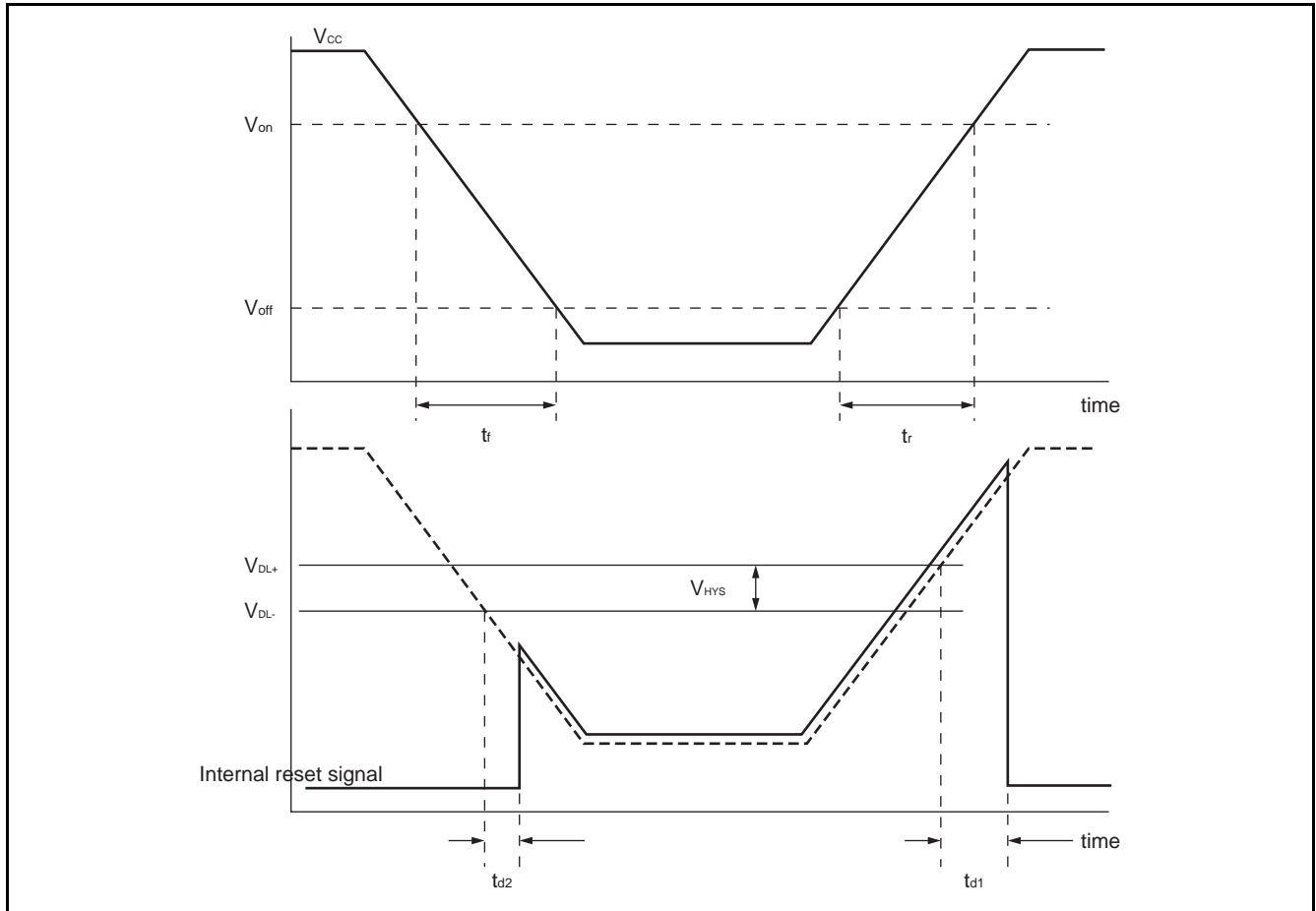


# MB95200H/210H Series

## (7) Low-voltage Detection

( $V_{SS} = 0.0\text{ V}$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ )

Parameter	Symbol	Value			Unit	Remarks
		Min	Typ	Max		
Release voltage	$V_{DL+}$	2.52	2.7	2.88	V	At power supply rise
Detection voltage	$V_{DL-}$	2.42	2.6	2.78	V	At power supply fall
Hysteresis width	$V_{HYS}$	70	100	—	mV	
Power supply start voltage	$V_{off}$	—	—	2.3	V	
Power supply end voltage	$V_{on}$	4.9	—	—	V	
Power supply voltage change time (at power supply rise)	$t_r$	1	—	—	$\mu\text{s}$	Slope of power supply that the reset release signal generates
		—	3000	—	$\mu\text{s}$	Slope of power supply that the reset release signal generates within the rating ( $V_{DL+}$ )
Power supply voltage change time (at power supply fall)	$t_r$	300	—	—	$\mu\text{s}$	Slope of power supply that the reset detection signal generates
		—	300	—	$\mu\text{s}$	Slope of power supply that the reset detection signal generates within the rating ( $V_{DL-}$ )
Reset release delay time	$t_{d1}$	—	—	300	$\mu\text{s}$	
Reset detection delay time	$t_{d2}$	—	—	20	$\mu\text{s}$	



# MB95200H/210H Series

## 5. A/D Converter

### (1) A/D Converter Electrical Characteristics

( $V_{CC} = 4.0 \text{ V to } 5.5 \text{ V}$ ,  $V_{SS} = 0.0 \text{ V}$ ,  $T_A = -40^\circ\text{C to } +85^\circ\text{C}$ )

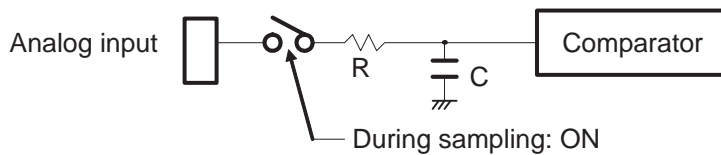
Parameter	Symbol	Value			Unit	Remarks
		Min	Typ	Max		
Resolution	—	—	—	10	bit	
Total error		-3	—	+3	LSB	
Linearity error		-2.5	—	+2.5	LSB	
Differential linear error		-1.9	—	+1.9	LSB	
Zero transition voltage	$V_{OT}$	$V_{SS}-1.5 \text{ LSB}$	$V_{SS}+0.5 \text{ LSB}$	$V_{SS}+2.5 \text{ LSB}$	V	
Full-scale transition voltage	$V_{FST}$	$V_{CC}-4.5 \text{ LSB}$	$V_{CC}-2 \text{ LSB}$	$V_{CC}+0.5 \text{ LSB}$	V	
Compare time	—	0.9	—	16500	$\mu\text{s}$	$4.5 \text{ V} \leq V_{CC} \leq 5.5 \text{ V}$
		1.8	—	16500	$\mu\text{s}$	$4.0 \text{ V} \leq V_{CC} < 4.5 \text{ V}$
Sampling time	—	0.6	—	$\infty$	$\mu\text{s}$	$4.5 \text{ V} \leq V_{CC} \leq 5.5 \text{ V}$ , with external impedance $< 5.4 \text{ k}\Omega$
		1.2	—	$\infty$	$\mu\text{s}$	$4.0 \text{ V} \leq V_{CC} \leq 4.5 \text{ V}$ , with external impedance $< 2.4 \text{ k}\Omega$
Analog input current	$I_{AIN}$	-0.3	—	+0.3	$\mu\text{A}$	
Analog input voltage	$V_{AIN}$	$V_{SS}$	—	$V_{CC}$	V	

## (2) Notes on Using the A/D Converter

### • External impedance of analog input and its sampling time

- The A/D converter has a sample and hold circuit. If the external impedance is too high to keep sufficient sampling time, the analog voltage charged to the internal sample and hold capacitor is insufficient, adversely affecting A/D conversion precision. Therefore, to satisfy the A/D conversion precision standard, considering the relationship between the external impedance and minimum sampling time, either adjust the register value and operating frequency or decrease the external impedance so that the sampling time is longer than the minimum value. In addition, if sufficient sampling time cannot be secured, connect a capacitor of about 0.1  $\mu\text{F}$  to the analog input pin.

#### • Analog input equivalent circuit

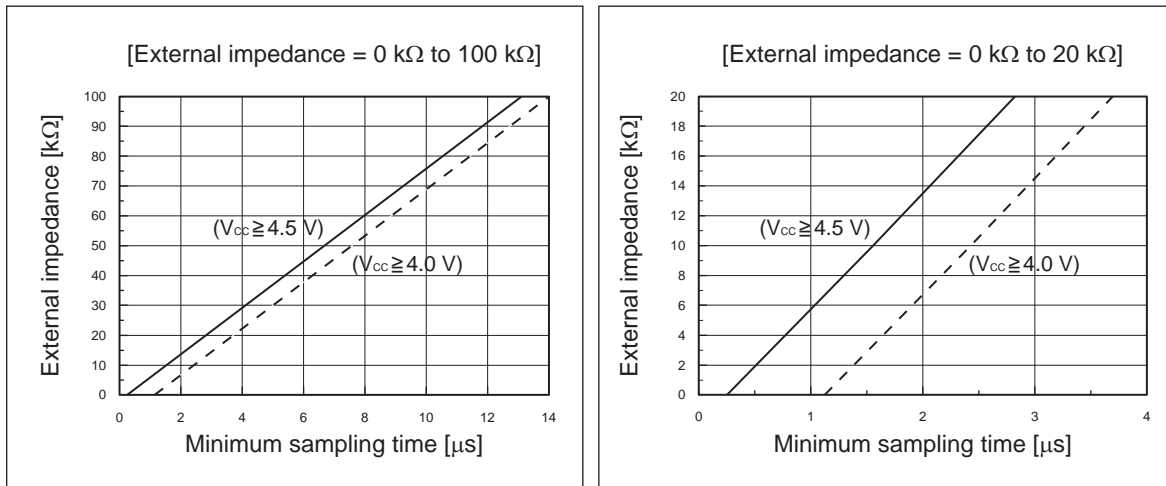


$$4.5 \text{ V} \leq V_{CC} \leq 5.5 \text{ V} : R \approx 1.95 \text{ k}\Omega \text{ (max)}, C \approx 17 \text{ pF (max)}$$

$$4.0 \text{ V} \leq V_{CC} < 4.5 \text{ V} : R \approx 8.98 \text{ k}\Omega \text{ (max)}, C \approx 17 \text{ pF (max)}$$

Note: The values are reference values.

#### • Relationship between external impedance and minimum sampling time

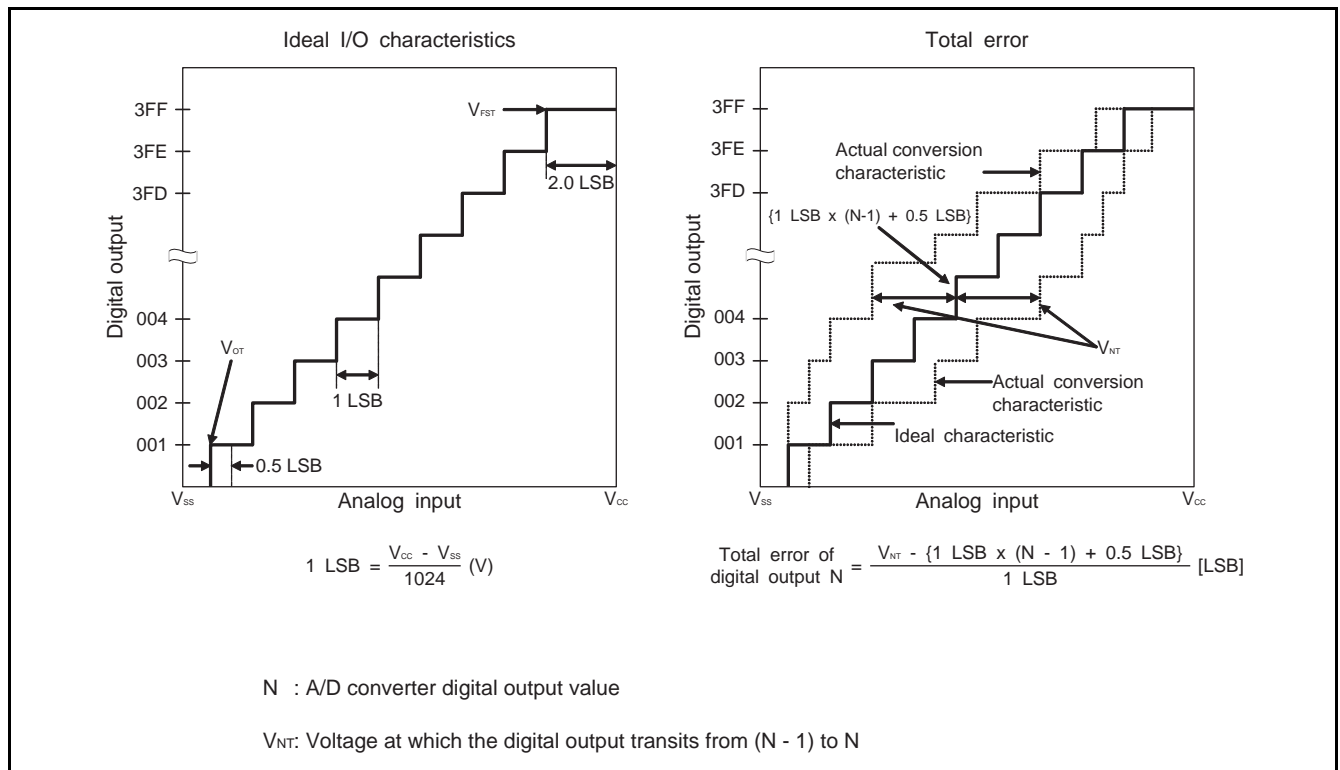


### • A/D conversion error

As  $V_{CC} - V_{SSl}$  decreases, the A/D conversion error increases proportionately.

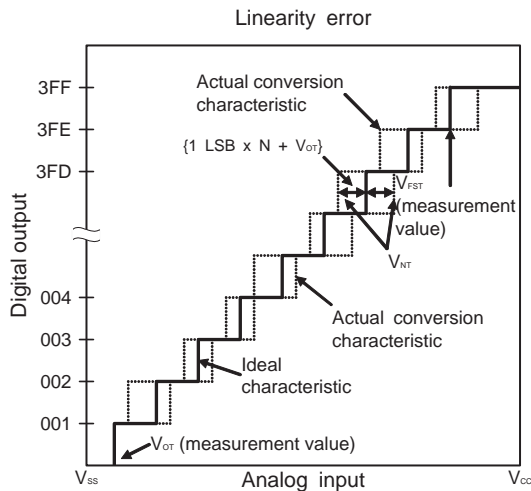
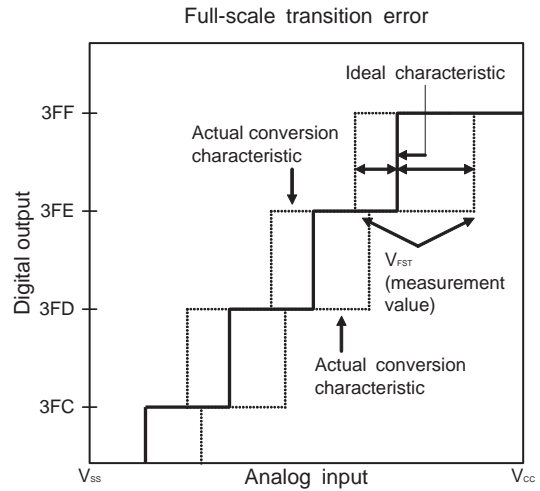
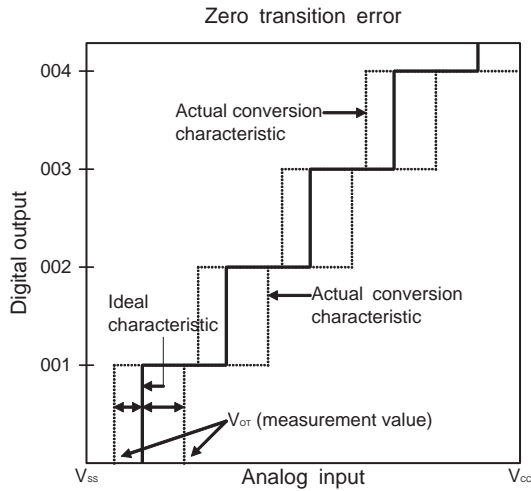
## (3) Definitions of A/D Converter Terms

- Resolution  
It indicates the level of analog variation that can be distinguished by the A/D converter.  
When the number of bits is 10, analog voltage can be divided into  $2^{10} = 1024$ .
- Linearity error (unit: LSB)  
It indicates how much an actual conversion value deviates from the straight line connecting the zero transition point ("00 0000 0000"  $\leftrightarrow$  "00 0000 0001") of a device to the full-scale transition point ("11 1111 1111"  $\leftrightarrow$  "11 1111 1110") of the same device.
- Differential linear error (unit: LSB)  
It indicates how much the input voltage required to change the output code by 1 LSB deviates from an ideal value.
- Total error (unit: LSB)  
It indicates the difference between an actual value and a theoretical value. The error can be caused by a zero transition error, a full-scale transition errors, a linearity error, a quantum error, or noise.

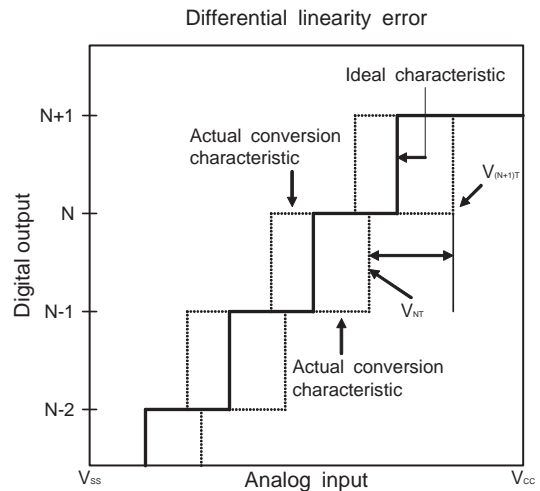


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$$\text{Linearity error of digital output } N = \frac{V_{NT} - \{1 \text{ LSB} \times N + V_{OT}\}}{1 \text{ LSB}}$$



$$\text{Differential linear error of digital output } N = \frac{V_{N+1T} - V_{NT}}{1 \text{ LSB}} - 1$$

$N$  : A/D converter digital output value

$V_{NT}$ : Voltage at which the digital output transits from  $(N - 1)$  to  $N$

$V_{OT}$  (ideal value) =  $V_{SS} + 0.5 \text{ LSB}$  [V]

$V_{FST}$  (ideal value) =  $V_{CC} - 2.0 \text{ LSB}$  [V]

# MB95200H/210H Series

## 6. Flash Memory Program/Erase Characteristics

Parameter	Value			Unit	Remarks
	Min	Typ	Max		
Chip erase time	—	1*1	15*2	s	00H programming time prior to erasure is excluded.
Byte programming time	—	32	3600	μs	System-level overhead is excluded.
Erase/program voltage	9.5	10	10.5	V	The erase/program voltage must be applied to the RSTX pin in erase/program.
Erase/program cycle	—	100000	—	cycle	
Power supply voltage at erase/program	4.5	—	5.5	V	
Flash memory data retention time	20*3	—	—	year	Average T <sub>A</sub> = +85°C

\*1: T<sub>A</sub> = +25°C, V<sub>CC</sub> = 5.0 V, 100000 cycles

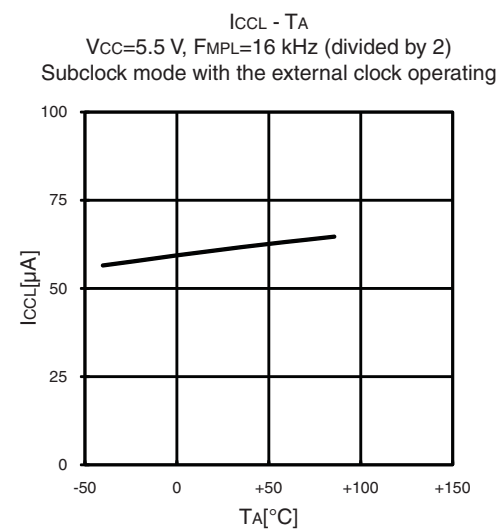
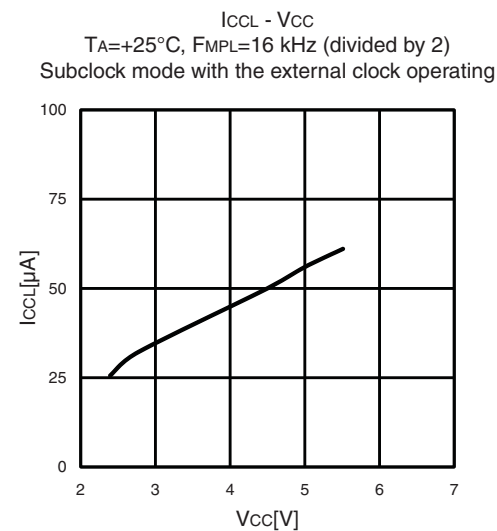
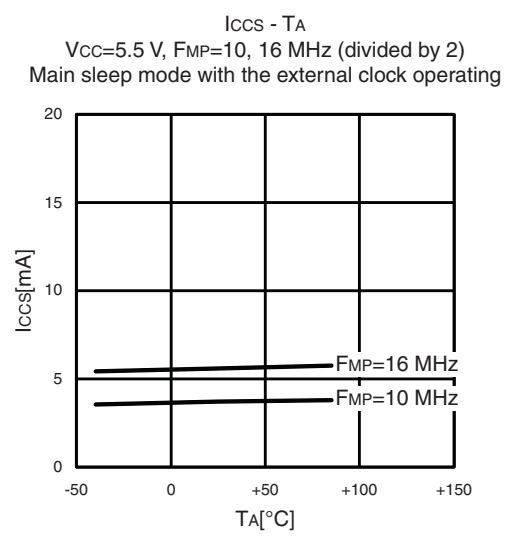
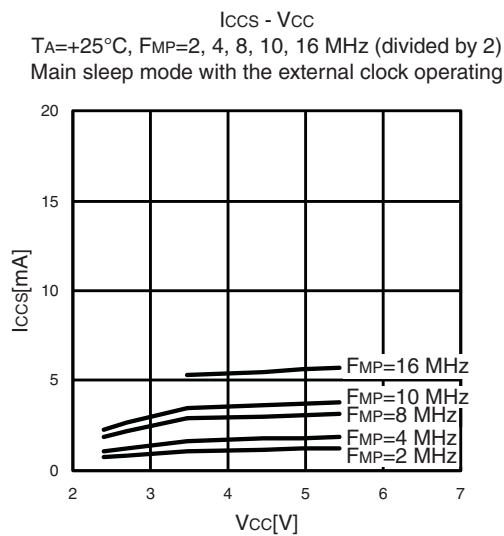
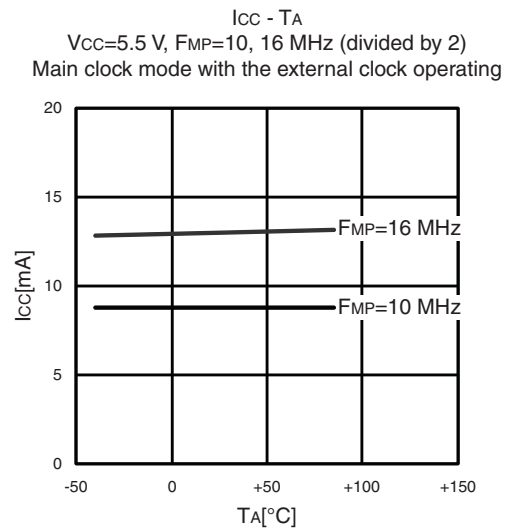
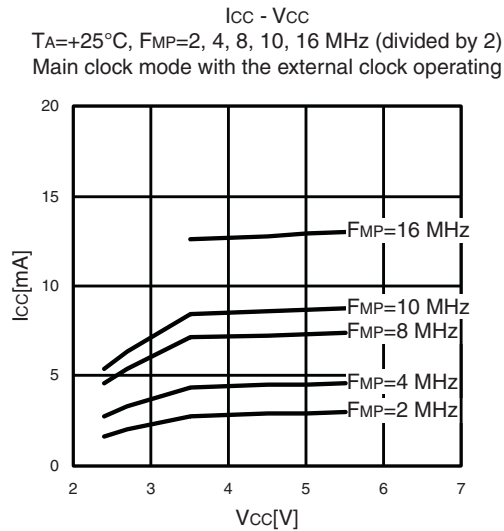
\*2: T<sub>A</sub> = +85°C, V<sub>CC</sub> = 4.5 V, 100000 cycles

\*3: This value is converted from the result of a technology reliability assessment. (The value is converted from the result of a high temperature accelerated test by using the Arrhenius equation with the average temperature being +85°C) .



## ■ SAMPLE ELECTRICAL CHARACTERISTICS

### • Power supply current • temperature

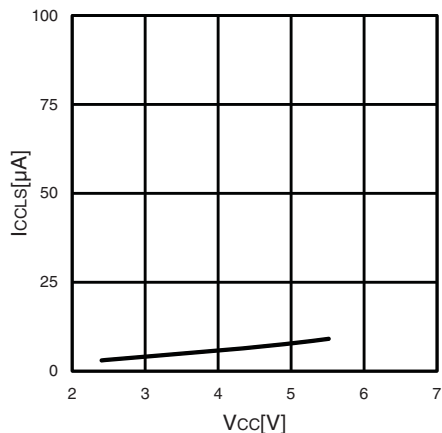


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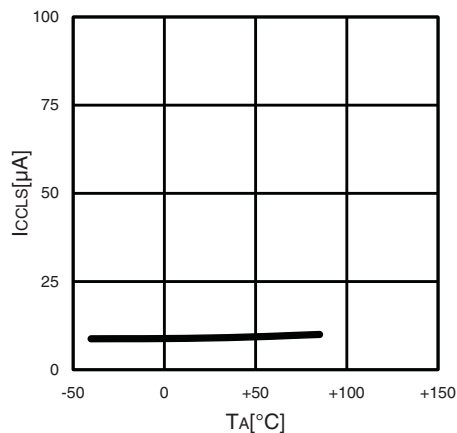
# MB95200H/210H Series

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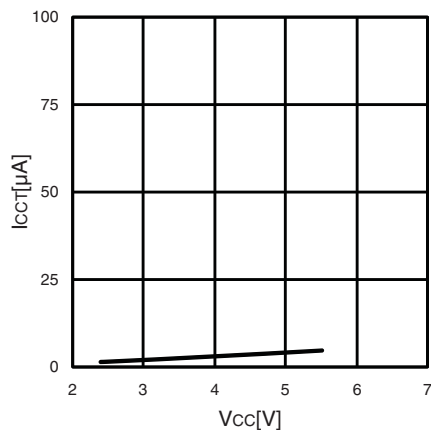
**ICCLS - VCC**  
 $T_A = +25^\circ\text{C}$ , FMPL=16 kHz (divided by 2)  
 Subsleep mode with the external clock operating



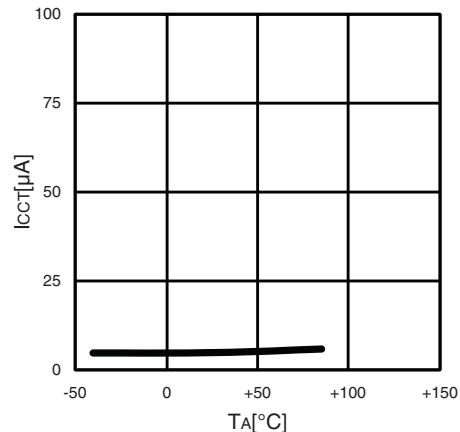
**ICCLS - TA**  
 $V_{CC} = 5.5\text{ V}$ , FMPL=16 kHz (divided by 2)  
 Subsleep mode with the external clock operating



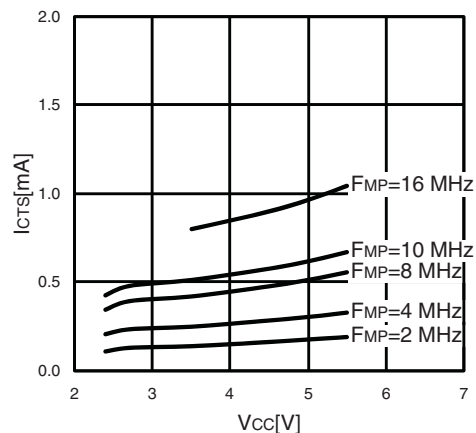
**ICCT - VCC**  
 $T_A = +25^\circ\text{C}$ , FMPL=16 kHz (divided by 2)  
 Clock mode with the external clock operating



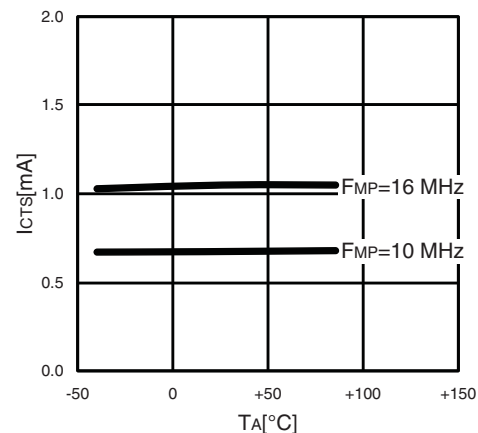
**ICCT - TA**  
 $V = 5.5\text{ V}$ , FMPL=16 kHz (divided by 2)  
 Clock mode with the external clock operating



**ICTS - VCC**  
 $T_A = +25^\circ\text{C}$ , FMP=2, 4, 8, 10, 16 MHz (divided by 2)  
 Timebase timer mode with the external clock operating

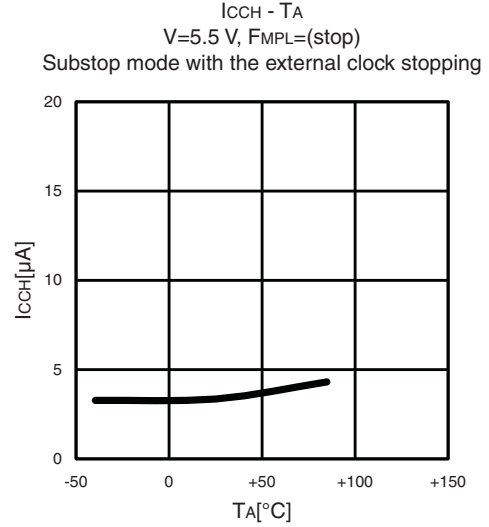
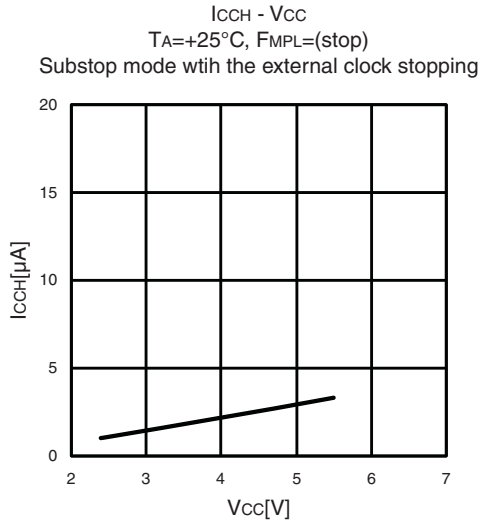


**ICTS - TA**  
 $V = 5.5\text{ V}$ , FMP=10, 16 MHz (divided by 2)  
 Timebase timer mode with the external clock operating

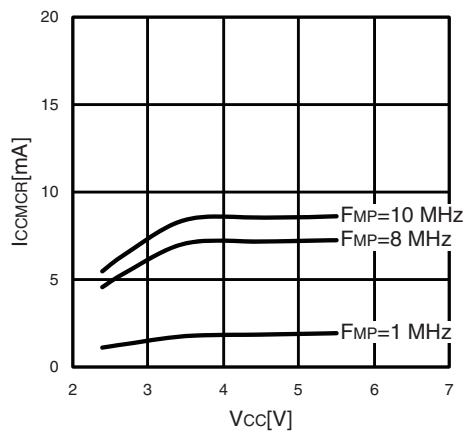


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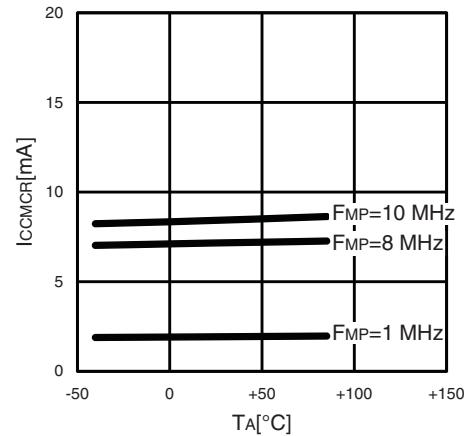
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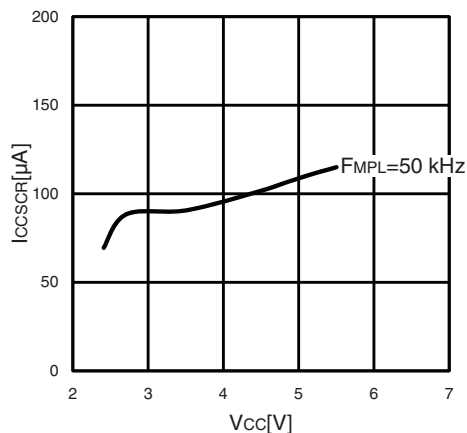
**ICCMCR - VCC**  
 $T_A = +25^\circ\text{C}$ , FMP=1, 8, 10 MHz (no division)  
 Main clock mode with the internal main CR clock operating



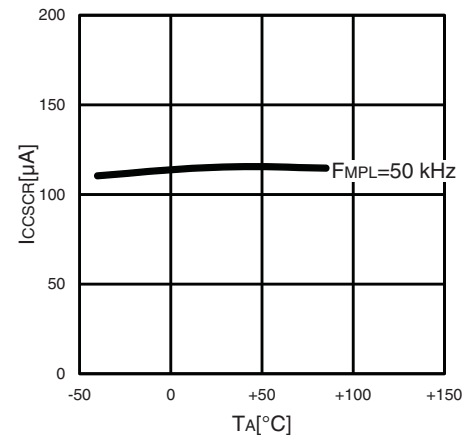
**ICCMCR - TA**  
 $V = 5.5\text{ V}$ , FMP=1, 8, 10 MHz (no division)  
 Main clock mode with the internal main CR clock operating



**ICCSSCR - VCC**  
 $T_A = +25^\circ\text{C}$ , FMPL=50 kHz (divided by 2)  
 Subclock mode with the internal sub-CR clock operating

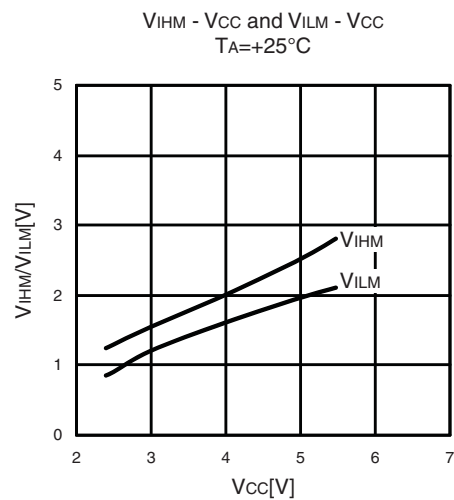
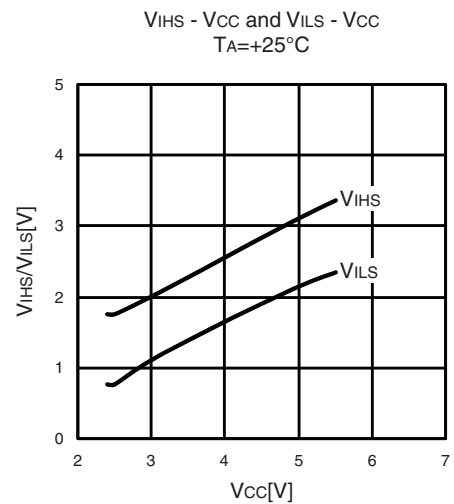
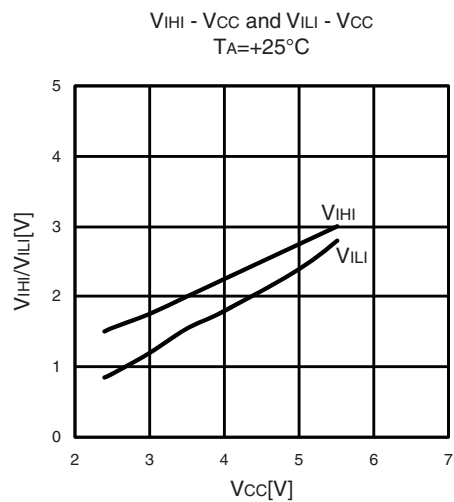


**ICCSSCR - TA**  
 $V_{CC} = 5.5\text{ V}$ , FMPL=50 kHz (divided by 2)  
 Subclock mode with the internal sub-CR clock operating

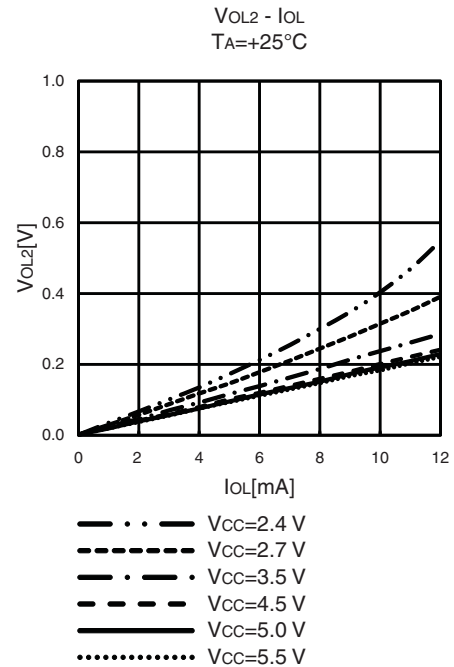
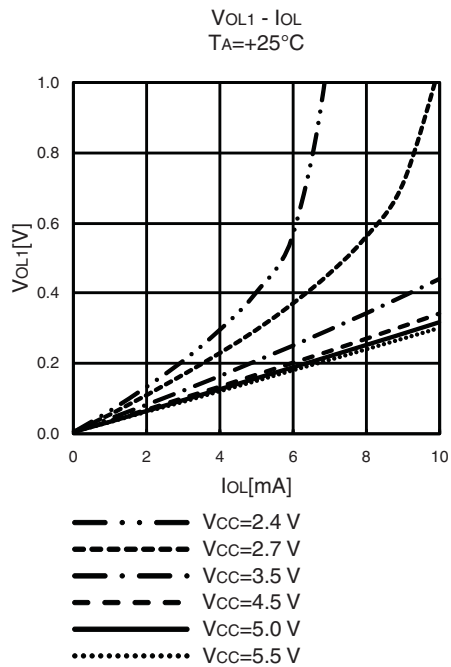
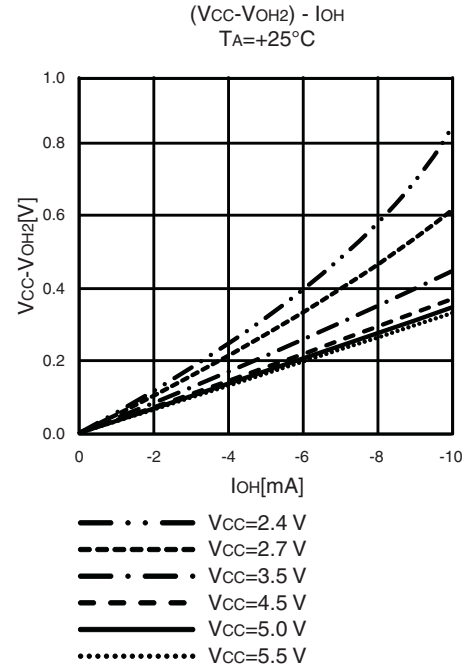
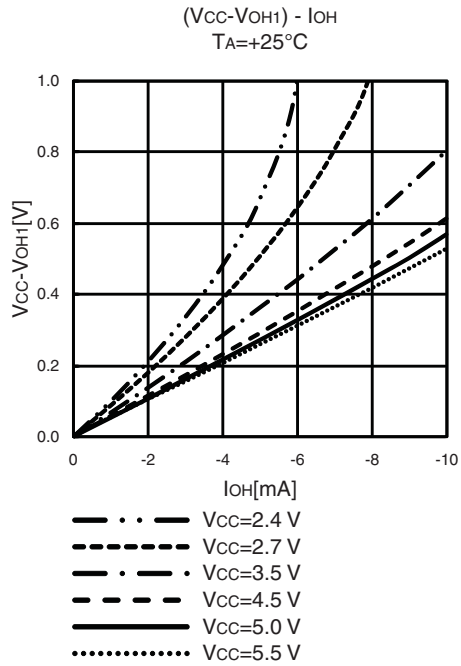


# MB95200H/210H Series

- Input voltage

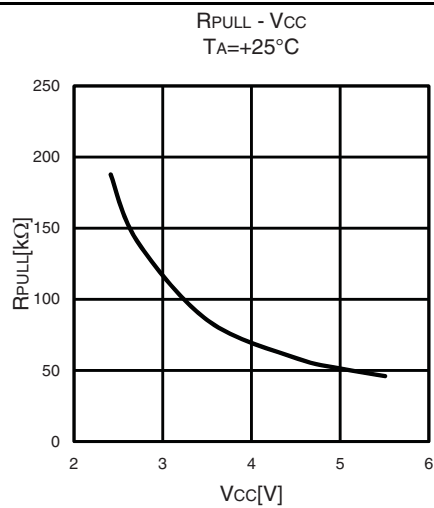


## • Output voltage



# MB95200H/210H Series

- Pull-up



## ■ MASK OPTIONS

No.	Part Number	MB95F204H MB95F203H MB95F202H MB95F214H MB95F213H MB95F212H	MB95F204K MB95F203K MB95F202K MB95F214K MB95F213K MB95F212K
	Selection Method	Setting disabled	Setting disabled
1	Low-voltage detection reset • With low-voltage detection reset • Without low-voltage detection reset	Without low-voltage detection reset	With low-voltage detection reset
2	Reset • With dedicated reset input • Without dedicated reset input	With dedicated reset input	Without dedicated reset input

# MB95200H/210H Series

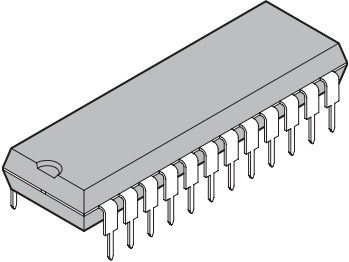
## ■ ORDERING INFORMATION

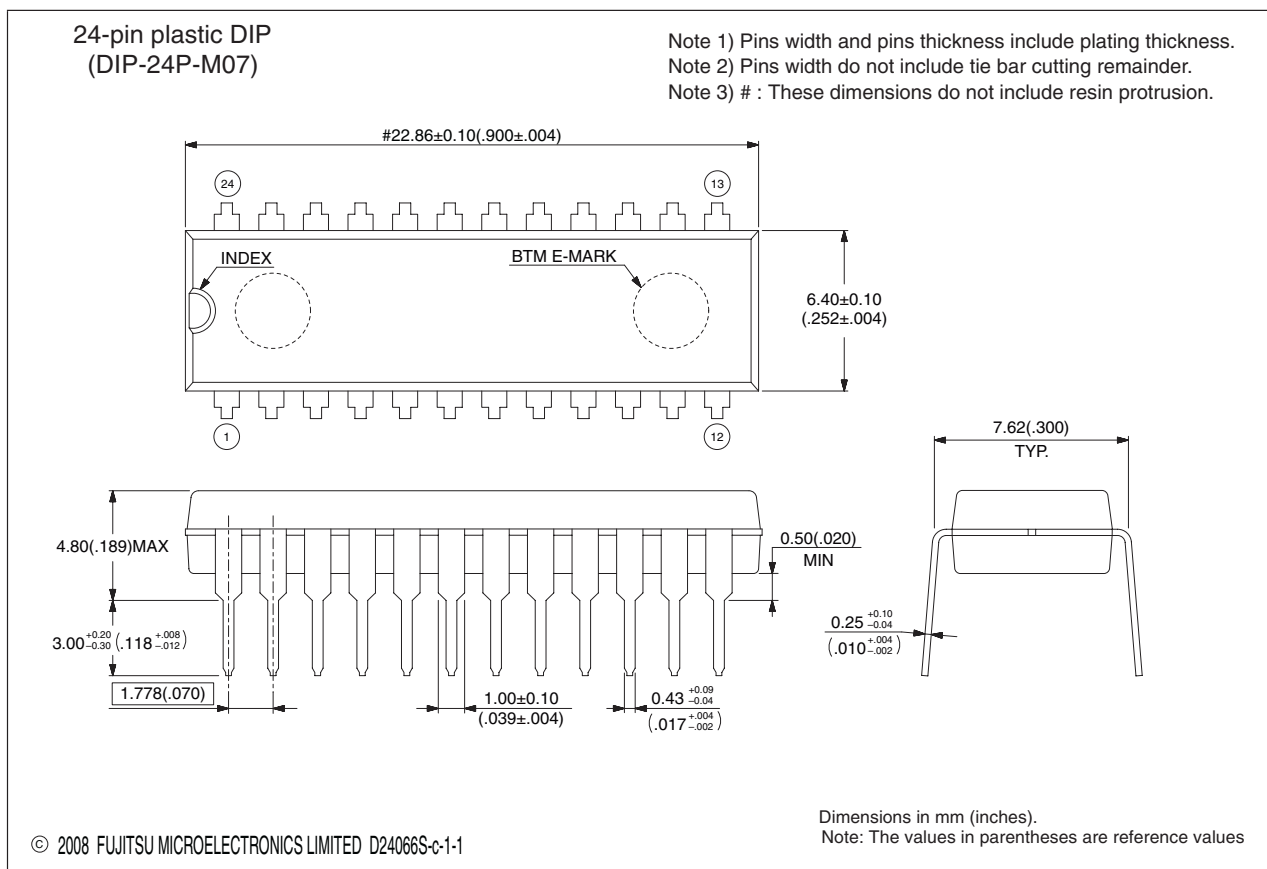
Part Number	Package
MB95F204HP-G-SH-SNE2 MB95F204KP-G-SH-SNE2 MB95F203HP-G-SH-SNE2 MB95F203KP-G-SH-SNE2 MB95F202HP-G-SH-SNE2 MB95F202KP-G-SH-SNE2	24-pin plastic SDIP (DIP-24P-M07)
MB95F204HPF-G-SNE2 MB95F204KPF-G-SNE2 MB95F203HPF-G-SNE2 MB95F203KPF-G-SNE2 MB95F202HPF-G-SNE2 MB95F202KPF-G-SNE2	20-pin plastic SOP (FPT-20P-M09)
MB95F214HPH-G-SNE2 MB95F214KPH-G-SNE2 MB95F213HPH-G-SNE2 MB95F213KPH-G-SNE2 MB95F212HPH-G-SNE2 MB95F212KPH-G-SNE2	8-pin plastic DIP (DIP-8P-M03)
MB95F214HPF-G-SNE2 MB95F214KPF-G-SNE2 MB95F213HPF-G-SNE2 MB95F213KPF-G-SNE2 MB95F212HPF-G-SNE2 MB95F212KPF-G-SNE2	8-pin plastic SOP (FPT-8P-M08)



# MB95200H/210H Series

## ■ PACKAGE DIMENSIONS

 <p>24-pin plastic DIP</p> <p>(DIP-24P-M07)</p>	Lead pitch	1.778 mm
	Package width package length	6.40 mm 22.86 mm
	Sealing method	Plastic mold
	Mounting height	4.80 mm Max

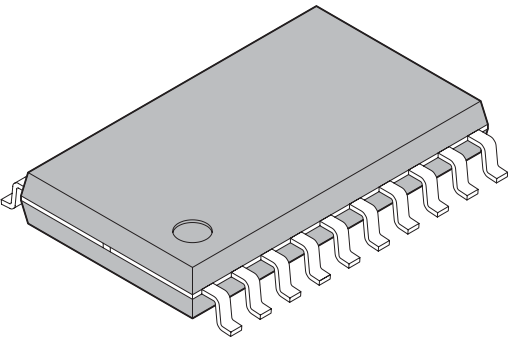


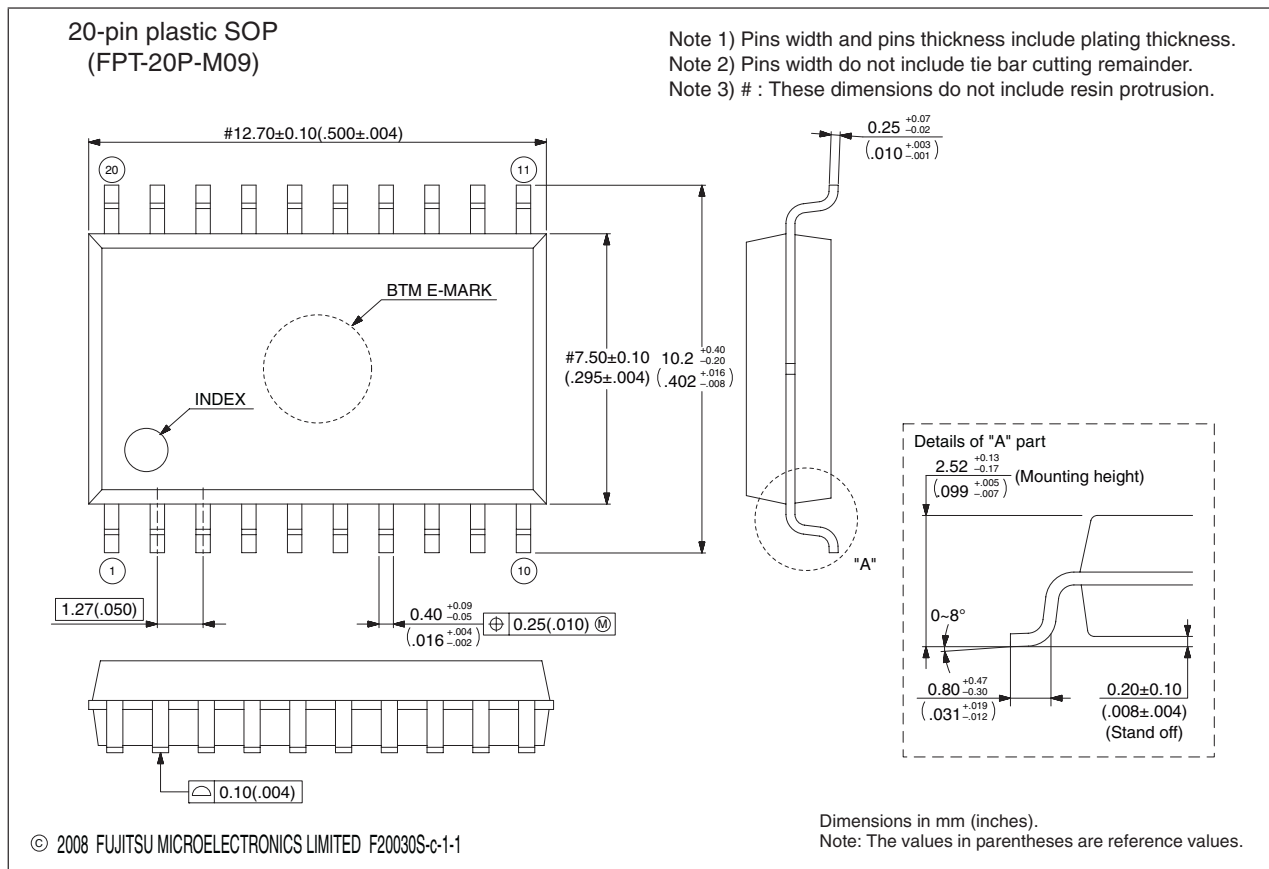
Please check the latest package dimensions at the following URL.  
<http://edevic.fujitsu.com/package/en-search/>

(Continued)

# MB95200H/210H Series

(Continued)

<p>20-pin plastic SOP</p>  <p>(FPT-20P-M09)</p>	Lead pitch	1.27 mm
	Package width package length	7.50 mm 12.70 mm
	Lead shape	Gullwing
	Lead bend direction	Normal bend
	Sealing method	Plastic mold
	Mounting height	2.65 mm Max

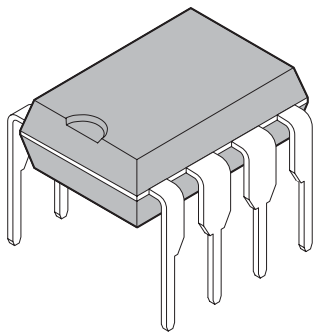


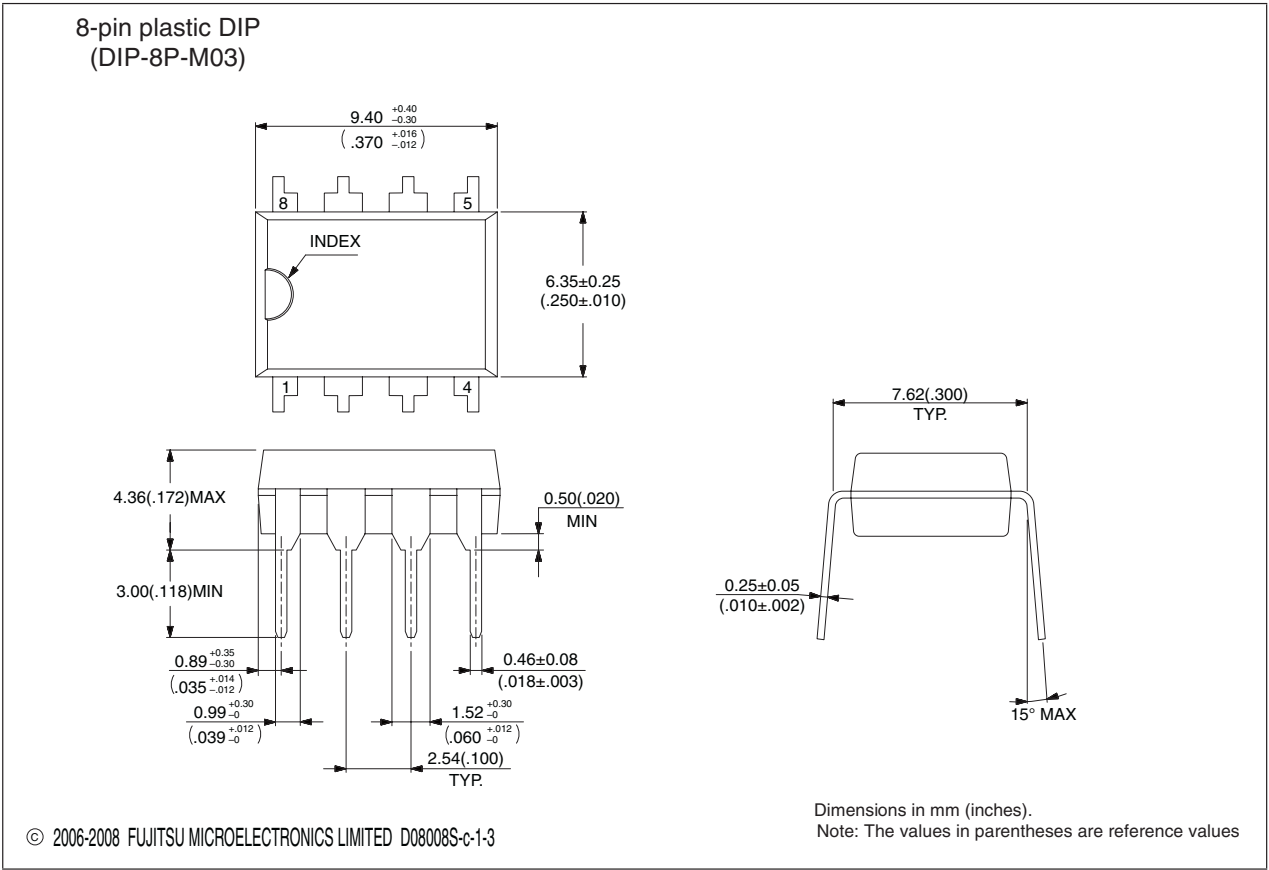
Please check the latest package dimensions at the following URL.  
<http://edevic.fujitsu.com/package/en-search/>

(Continued)

# MB95200H/210H Series

(Continued)

<div>8-pin plastic DIP</div>  <div>(DIP-8P-M03)</div>	Lead pitch	2.54 mm
	Sealing method	Plastic mold

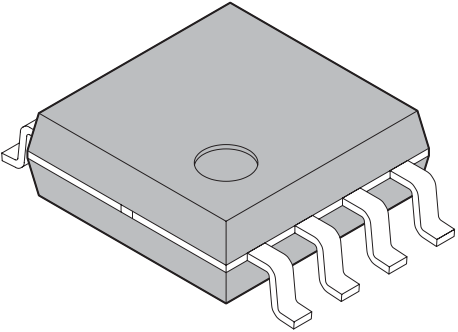


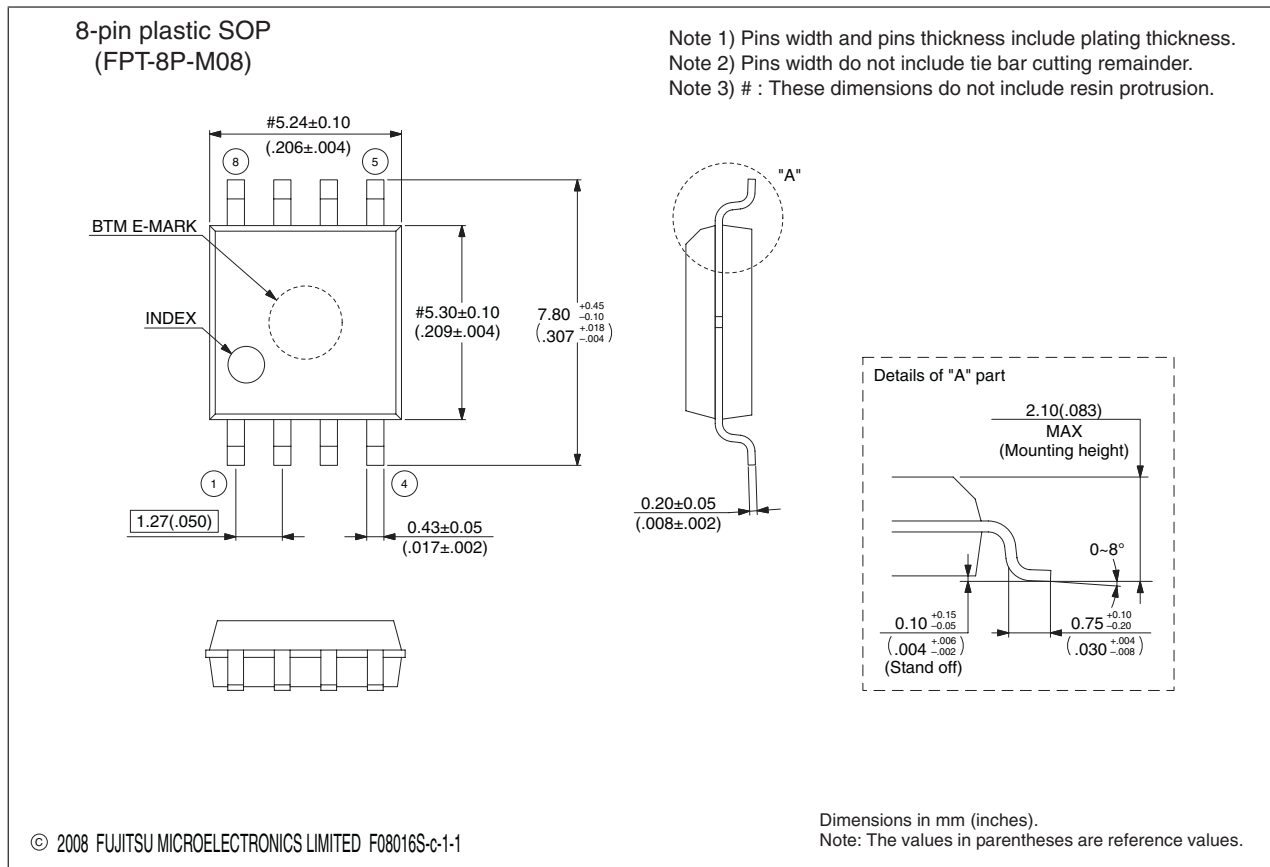
Please check the latest package dimensions at the following URL.  
<http://edevic.fujitsu.com/package/en-search/>

(Continued)

# MB95200H/210H Series

(Continued)

 <p>8-pin plastic SOP</p> <p>(FPT-8P-M08)</p>	Lead pitch	1.27 mm
	Package width package length	5.30 mm 5.24 mm
	Lead shape	Gullwing
	Lead bend direction	Normal bend
	Sealing method	Plastic mold
	Mounting height	2.10 mm Max



Please check the latest package dimensions at the following URL.  
<http://edevic.fujitsu.com/package/en-search/>

## ■ MAJOR REVISIONS IN THIS EDITION

Page	Section	Revision Details
—	—	Preliminary Data Sheet → Data Sheet
—	■ PROGRAMMING FLASH MEMORY MICROCONTROLLERS USING SERIAL PROGRAMMER	This section was deleted.
57 to 62	■ SAMPLE ELECTRICAL CHARACTERISTICS	This is a new section.

MEMO

**MEMO**

# MB95200H/210H Series

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